

# Theory of surface Andreev bound states and tunneling spectroscopy in three-dimensional chiral superconductors

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We study the surface Andreev bound states (SABSs) and quasiparticle tunneling spectroscopy of three-dimensional (3D) chiral superconductors by changing their surface (interface) misorientation angles. We obtain an analytical formula for the SABS energy dispersion of a general pair potential, for which an original  $4 \times 4$  BdG Hamiltonian can be reduced to two  $2 \times 2$  blocks. The resulting SABS for 3D chiral superconductors with a pair potential given by  $k_z(k_x + ik_y)^\nu$  ( $\nu = 1, 2$ ) has a complicated energy dispersion owing to the coexistence of both point and line nodes. We focus on the tunneling spectroscopy of this pairing in the presence of an applied magnetic field, which induces a Doppler shift in the quasiparticle spectra. In contrast to the previously known Doppler effect in unconventional superconductors, a zero-bias conductance dip can change into a zero-bias conductance peak owing to an external magnetic field. We also study SABSs and tunneling spectroscopy for possible pairing symmetries of  $U\text{Pt}_3$ . For this purpose, we extend a standard formula for the tunneling conductance of unconventional superconductor junctions to treat spin-triplet nonunitary pairings. Magnetotunneling spectroscopy, i.e., tunneling spectroscopy in the presence of a magnetic field, can serve as a guide to determine the pairing symmetry of this material.

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## I. INTRODUCTION

The surface Andreev bound state (SABS) is one of the key concepts regarding unconventional superconductors [1–3]. To date, various types of SABSs have been revealed in two-dimensional (2D) unconventional superconductors [4,5]. It is known that a flat band SABS exists in a spin-singlet  $d$ -wave superconductor [6] that is protected by a topological invariant defined in the bulk Hamiltonian [4,7–9]. The ubiquitous presence of this zero energy SABS manifests itself as a zero-bias conductance peak (ZBCP) in the tunneling spectroscopy of high- $T_c$  cuprates [10–16]. There has been interest in the spin-triplet  $p$ -wave superconductor [17,18] with a flat band SABS and sharp ZBCP, similar to the  $d$ -wave case [19–21]. Apart from flat bands, it is known that chiral  $p$ -wave superconductors host a SABS with a linear dispersion as a function of momentum parallel to the edge, resulting in a much broader ZBCP [21–25].

Magnetotunneling spectroscopy, i.e., tunneling spectroscopy in the presence of an applied magnetic field, is a powerful tool to make distinctions among pairing symmetries. Under an applied magnetic field, the shift of quasiparticle energy spectra, which is proportional to the transverse momentum, is generally known as the Doppler effect [13,26]. It has been shown that the splitting of the ZBCP occurs in  $d$ -wave superconductor junctions owing to this [13,26]. In contrast, for spin-triplet  $p$ -wave cases, the ZBCP does not split into two [20] since the perpendicular injection of quasiparticles dominantly contributes to the tunneling conductance. For perpendicular injection, the component of the Fermi velocity parallel to the interface is zero and there is no energy shift of the quasiparticles. Therefore we can distinguish between  $d$ - and  $p$ -wave pairing with magnetotunneling spectroscopy [27]. For chiral  $p$ -wave superconductors, the magnitude of the

ZBCP is enhanced or suppressed depending on the direction of the applied magnetic field [20]. Chiral and helical superconductors also exhibit different features of magnetotunneling spectroscopy, whereas both of these superconductors have similarly broad ZBCP without magnetic field [28]. In any case, a ZBCP generated from a zero-bias conductance dip by applying magnetic field has not been found.

For three-dimensional (3D) unconventional superconductors, the energy dispersion of SABS becomes more complicated [17,29–40]. Recently, the SABSs of 3D chiral superconductors have been studied [41], where a pair potential is given by  $\Delta_0 k_z(k_x + ik_y)^\nu/k_F^{\nu+1}$  with a nonzero integer  $\nu$ . These pairing symmetries are relevant to typical heavy fermion superconductors with  $\nu = 1$  and  $\nu = 2$ , corresponding to the candidate pairing symmetries of  $\text{URu}_2\text{Si}_2$  [42–44] and  $U\text{Pt}_3$  [45–50], respectively. The simultaneous presence of line and point nodes gives rise to exotic SABS. It has been shown that the flat band SABS is found to be fragile against the surface misorientation angle  $\alpha$ , as shown in Fig. 1. Although the topological natures of the flat band SABS have been clarified [41], the overall features of the energy dispersion of the SABS have not been systematically analyzed. Thus it is a challenging issue to identify 3D pairing states theoretically in terms of magnetotunneling spectroscopy.

In this work, we study the SABS and quasiparticle tunneling spectroscopy of 3D chiral superconductors by changing the surface (interface) misorientation angle  $\alpha$ . For this purpose, we analytically derive a formula for the energy dispersion of SABSs available of a general pair potential, for which an original  $4 \times 4$  matrix of a Bogoliubov-de Gennes (BdG) Hamiltonian can be decomposed into two blocks of  $2 \times 2$  matrices. We apply this formula to 3D chiral superconductors with a pair potential given by  $\Delta_0 k_z(k_x + ik_y)^\nu/k_F^{\nu+1}$  ( $\nu = 1, 2$ ).

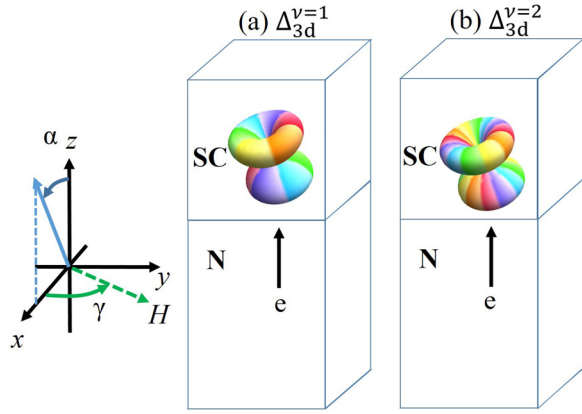


FIG. 1. We mainly consider above two types of normal (N)-superconductor (SC) junctions. Here,  $\alpha$  is the misorientation angle from the  $k_z$  axis. Magnetic field is applied in the  $x$ - $y$  plane, rotated from the  $x$  axis by  $\gamma$ .

The resulting SABS has a complex momentum dependence due to the coexistence of point and line nodes. SABSs arising from topological and nontopological origins are found to coexist. The number of branches of the energy dispersion of SABSs with topological origin can be classified by  $\nu$  for various  $\alpha$ . On the other hand, if we apply our formula to 2D-like chiral superconductors with a pair potential given by  $\Delta_0(k_x + ik_y)^\nu/k_F^\nu$  ( $\nu = 1, 2$ ), the number of branches of SABSs is equal to  $2\nu$ , where the pair potential has only point nodes.

In order to distinguish between two 3D chiral superconductors with different  $\nu$ , we calculate the tunneling conductance of normal metal/insulator/chiral superconductor junctions in the presence of an applied magnetic field, which induces a Doppler shift. The obtained angle-resolved conductance has a complicated momentum dependence reflecting on the dispersion of SABS for nonzero  $\alpha$ . In contrast to previous studies of the Doppler effect on tunneling conductance, a zero-bias conductance dip can evolve into a ZBCP by applying magnetic field. This unique feature stems from the complex nodal structures of the pair potential where both line and point nodes coexist. Furthermore, we focus on four possible candidates of the pairing symmetry of  $UPT_3$ , where the momentum dependencies of the pair potentials are proportional to  $k_z(k_x + ik_y)^2 d_z$ ,  $(5k_z^2 - k_F^2)(k_x + ik_y)d_z$ ,  $(5k_z^2 - k_F^2)(d_y k_x + d_z k_y)$ , and  $f + p$ -wave belonging to the  $E_{2u}$  representation. Here, we derive a general formula for tunneling conductance, which is available even for nonunitary spin-triplet superconductors. We show that these four pairings can be classified by using magneto tunneling spectroscopy. Thus our theory serves as a guide to determine the pairing symmetry of  $UPT_3$ .

The remainder of this paper is organized as follows. In Sec. II, we explain the model and formulation. We analytically derive a formula for the energy dispersion of SABSs available for a general pair potential for which an original  $4 \times 4$  matrix of BdG Hamiltonian is decomposed into two blocks of  $2 \times 2$  matrices. We also derive a general conductance formula, available even for nonunitary spin-triplet pairing cases. Besides these, to understand the topological origin of

SABS, we calculate winding number. In Sec. III A, based on above formula, we calculate the SABS and tunneling conductance for 3D chiral superconductors for various  $\alpha$ . As a reference, we also calculate the SABS for 2D-like chiral superconductors. In Sec. III B, we calculate the tunneling conductance in the presence of an external magnetic field using so-called magnetotunneling spectroscopy. In Sec. III C, we study the SABS and tunneling conductance for promising pairing symmetries of  $UPT_3$ . In Sec. IV, we summarize our results.

## II. MODEL AND METHOD

In this section, we introduce the mean-field Hamiltonian of 3D chiral superconductors. We derive an analytical formula for SABS for which the original  $4 \times 4$  BdG Hamiltonian can be reduced to be two blocks of  $2 \times 2$  matrices. We calculate the tunneling conductance in the presence of an external applied magnetic field. In order to study the case of nonunitary spin-triplet pairings, we derive an analytical formula for the tunneling conductance. The bulk BdG Hamiltonian is given as follows:

$$\mathcal{H} = \frac{1}{2} \sum_{\mathbf{k}} \Psi^\dagger(\mathbf{k}) H(\mathbf{k}) \Psi(\mathbf{k}),$$

$$H(\mathbf{k}) = \begin{pmatrix} \hat{\varepsilon}(\mathbf{k}) & \Delta(\mathbf{k}) \\ \Delta^\dagger(\mathbf{k}) & -\hat{\varepsilon}(-\mathbf{k}) \end{pmatrix}, \quad (1)$$

$$\Psi(\mathbf{k}) = (c_{\mathbf{k},\uparrow}, c_{\mathbf{k},\downarrow}, c_{-\mathbf{k},\uparrow}^\dagger, c_{-\mathbf{k},\downarrow}^\dagger)^T,$$

where  $\hat{\varepsilon}(\mathbf{k}) = \text{diag}[\varepsilon(\mathbf{k}), \varepsilon(\mathbf{k})]$  and  $\Delta(\mathbf{k})$  are  $2 \times 2$  matrices. Here,  $\varepsilon(\mathbf{k})$  denotes the energy dispersion  $\hbar^2 \mathbf{k}^2 / (2m) - \mu$  in the normal state. For spin-triplet pairing, the pair potential is given by

$$\Delta = \mathbf{d} \cdot \boldsymbol{\sigma} i \sigma_2,$$

by using a  $\mathbf{d}$  vector, where  $(\sigma_1, \sigma_2, \sigma_3) = \boldsymbol{\sigma}$  are the Pauli matrices. We consider normal metal ( $z < 0$ )/superconductor ( $z > 0$ ) junctions with a flat interface, as shown in Fig. 1. The momentum parallel to the interface  $\mathbf{k}_{\parallel} = (k_x, k_y)$  becomes a good quantum number.

In the following, we explain eight types of pair potentials and corresponding formulas for tunneling conductance and SABS. In Sec. II A, we explain the case for which the BdG Hamiltonian can be reduced to a  $2 \times 2$  form [ $\Delta_{3d}^{\nu=0,1,2}$ ,  $\Delta_{2d}^{\nu=1,2}$ , and  $\Delta_{E_{1u}}^{\text{chiral}}$ ]. In Sec. II B, we explain the case for which the  $4 \times 4$  BdG Hamiltonian cannot be reduced to two  $2 \times 2$  blocks [ $\Delta_{E_{1u}}^{\text{planar}}$  and  $\Delta_{E_{2u}}^{f+p}$ ]. In Sec. II C, we briefly summarize the zero-energy SABS (ZESABS) stemming from topological numbers.

### A. $2 \times 2$ BdG Hamiltonian

In this section, we introduce pair potentials for 3D and 2D-like chiral superconductors. We derive a formula for the SABS for which the BdG Hamiltonian can be reduced to two  $2 \times 2$  matrices.  $\Delta(\mathbf{k})$  takes

$$\Delta_{3d}^{\nu}(\mathbf{k}) = \begin{cases} \tilde{\Delta}_{3d}^{\nu} i \sigma_2 & \nu : \text{odd}, \\ \tilde{\Delta}_{3d}^{\nu} \sigma_3 i \sigma_2 & \nu : \text{even}, \end{cases} \quad (2)$$

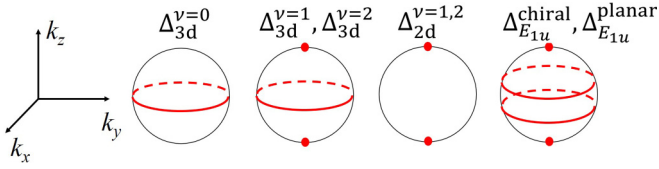


FIG. 2. Schematic illustration of nodal structures of  $\Delta(\mathbf{k})$  with  $\alpha = 0$ . Red points and lines indicate the positions of nodes.

$$\Delta_{2d}^v(\mathbf{k}) = \begin{cases} s\tilde{\Delta}_{2d}^v\sigma_3i\sigma_2 & v : \text{odd}, \\ \tilde{\Delta}_{2d}^vi\sigma_2 & v : \text{even}, \end{cases} \quad (3)$$

$$\Delta_{E_{1u}}^{\text{chiral}}(\mathbf{k}) = \tilde{\Delta}_{E_{1u}}^{\text{chiral}}\sigma_3i\sigma_2, \quad (4)$$

$$\tilde{\Delta}_{3d}^v = \frac{\Delta_0}{r_{3d,v}k_F^{v+1}}k'_z(k'_x + ik'_y)^v,$$

$$\tilde{\Delta}_{2d}^v = \frac{\Delta_0}{k_F^v}(k'_x + ik'_y)^v,$$

$$\tilde{\Delta}_{E_{1u}}^{\text{chiral}} = \frac{\Delta_0}{r_{E_{1u}}k_F^3}(5k_z'^2 - k_F^2)(k'_x + ik'_y),$$

$$k'_x = k_x \cos \alpha - k_z \sin \alpha,$$

$$k'_y = k_y,$$

$$k'_z = k_x \sin \alpha + k_z \cos \alpha,$$

where  $\alpha$  is the misorientation angle from the  $k_z$  axis and  $(r_{3d,v=0}, r_{3d,v=1}, r_{3d,v=2}, r_{E_{1u}}) = (1, 1/2, 2/\sqrt{27}, 16/(3\sqrt{15}))$  are the normalization factors so that the maximum value of the pair potential becomes  $\Delta_0$ . Because the direction of the  $\mathbf{d}$  vector in spin-space does not affect conductance, i.e., conductance is invariant under spin rotation (Appendix C3), we fix the direction of the  $\mathbf{d}$  vector given in Eqs. (2)–(4) for the spin-triplet cases.  $\Delta_{3d}^v$  and  $\Delta_{2d}^v$  are chosen in Secs. III A and III B. We study  $\Delta_{3d}^{v=2}$  and  $\Delta_{E_{1u}}^{\text{chiral}}$  in Sec. III C. Under the quasiclassical approximation, the magnitude of the wave vector is pinned to the value on the Fermi surface,  $k_z = \sqrt{k_F^2 - k_x^2 - k_y^2}$ . As shown in Fig. 2,  $\Delta_{3d}^{v=0}$  has a line node,  $\Delta_{3d}^v$  ( $v = 1, 2$ ) has two point nodes and one line node, and  $\Delta_{2d}^v$  ( $v > 0$ ) has two point nodes.  $\Delta_{E_{1u}}^{\text{chiral}}$  has two point nodes and two line nodes.

Then, we show that the BdG Hamiltonian can be reduced to a  $2 \times 2$  form for all the cases. For the spin-singlet cases ( $\Delta_{3d}^{v=1}$  and  $\Delta_{2d}^{v=2}$ ), Eq. (1) is reduced to

$$\begin{aligned} \mathcal{H}(\mathbf{k}) &= \frac{1}{2} \sum_{\mathbf{k}} \Psi^\dagger(\mathbf{k}) \begin{pmatrix} \varepsilon(\mathbf{k}) & 0 & 0 & D \\ 0 & \varepsilon(\mathbf{k}) & -D & 0 \\ 0 & -D^* & -\varepsilon(\mathbf{k}) & 0 \\ D^* & 0 & 0 & -\varepsilon(\mathbf{k}) \end{pmatrix} \Psi(\mathbf{k}) \\ &= \frac{1}{2} \sum_{\mathbf{k}} (c_{\mathbf{k},\uparrow}^\dagger \ c_{-\mathbf{k},\downarrow}) \begin{pmatrix} \varepsilon(\mathbf{k}) & D \\ D^* & -\varepsilon(\mathbf{k}) \end{pmatrix} \begin{pmatrix} c_{\mathbf{k},\uparrow} \\ c_{-\mathbf{k},\downarrow} \end{pmatrix} \\ &\quad + \frac{1}{2} \sum_{\mathbf{k}} (c_{\mathbf{k},\downarrow}^\dagger \ c_{-\mathbf{k},\uparrow}) \begin{pmatrix} \varepsilon(\mathbf{k}) & -D \\ -D^* & -\varepsilon(\mathbf{k}) \end{pmatrix} \begin{pmatrix} c_{\mathbf{k},\downarrow} \\ c_{-\mathbf{k},\uparrow} \end{pmatrix}, \end{aligned}$$

with  $D i\sigma_2 = \Delta_{3d}^{v=1}$  or  $\Delta_{2d}^{v=2}$ . For the spin-triplet cases ( $\Delta_{3d}^{v=0,2}$ ,  $\Delta_{2d}^{v=1}$ , and  $\Delta_{E_{1u}}^{\text{chiral}}$ ), with a  $\mathbf{d}$  vector, Eq. (1) becomes

$$\begin{aligned} \mathcal{H}(\mathbf{k}) &= \frac{1}{2} \sum_{\mathbf{k}} \Psi^\dagger(\mathbf{k}) \begin{pmatrix} \varepsilon(\mathbf{k}) & 0 & 0 & d_3 \\ 0 & \varepsilon(\mathbf{k}) & d_3 & 0 \\ 0 & d_3^* & -\varepsilon(\mathbf{k}) & 0 \\ d_3^* & 0 & 0 & -\varepsilon(\mathbf{k}) \end{pmatrix} \Psi(\mathbf{k}) \\ &= \frac{1}{2} \sum_{\mathbf{k}} (c_{\mathbf{k},\uparrow}^\dagger \ c_{-\mathbf{k},\downarrow}) \begin{pmatrix} \varepsilon(\mathbf{k}) & d_3 \\ d_3^* & -\varepsilon(\mathbf{k}) \end{pmatrix} \begin{pmatrix} c_{\mathbf{k},\uparrow} \\ c_{-\mathbf{k},\downarrow} \end{pmatrix} \\ &\quad + \frac{1}{2} \sum_{\mathbf{k}} (c_{\mathbf{k},\downarrow}^\dagger \ c_{-\mathbf{k},\uparrow}) \begin{pmatrix} \varepsilon(\mathbf{k}) & d_3 \\ d_3^* & -\varepsilon(\mathbf{k}) \end{pmatrix} \begin{pmatrix} c_{\mathbf{k},\downarrow} \\ c_{-\mathbf{k},\uparrow} \end{pmatrix}, \end{aligned}$$

with  $(d_3\sigma_3)(i\sigma_2) = \Delta_{3d}^{v=2}$ ,  $\Delta_{2d}^{v=1}$ , or  $\Delta_{E_{1u}}^{\text{chiral}}$ .

In the following, we calculate the charge conductance by using the extended version [1,10,51] of the Blonder–Tinkham–Klapwijk (BTK) formula [52] for unconventional superconductors [53]. Since we assume that the penetration depth of the magnetic field  $\lambda$  is much larger than the coherence length of the pair potential [26,54], we can neglect the spatial dependence of the magnetic field. Therefore we can take the vector potential as

$$\mathbf{A} = (-H\lambda \sin \gamma, H\lambda \cos \gamma, 0). \quad (5)$$

Solving the BdG equation with the quasiclassical approximation, where  $\mu$  is much larger than the energy of an injected electron  $|eV|$  and  $|\Delta(\mathbf{k}_\parallel)|$ , the wave function in the normal metal (N) and superconductor (S) are obtained as

$$\begin{aligned} \Psi_\sigma^N(z < 0, \mathbf{k}_\parallel) &= \psi_{e,\sigma}^N e^{i\mathbf{k}\cdot\mathbf{r}} + \sum_{\sigma'=\pm} (a_{\sigma,\sigma'} \psi_{h,\sigma'}^N e^{i\mathbf{k}\cdot\mathbf{r}} + b_{\sigma,\sigma'} \psi_{e,\sigma'}^N e^{i\tilde{\mathbf{k}}\cdot\mathbf{r}}), \quad (6) \end{aligned}$$

$$\Psi^S(z > 0, \mathbf{k}_\parallel) = \sum_{\sigma'=\pm} (c_{\sigma'} \psi_{e,\sigma'}^S e^{i\mathbf{k}\cdot\mathbf{r}} + d_{\sigma'} \psi_{h,\sigma'}^S e^{i\tilde{\mathbf{k}}\cdot\mathbf{r}}), \quad (7)$$

and

$$\psi_{e,\sigma}^N = (1 + \sigma, 1 - \sigma, 0, 0)^T/2, \quad (8)$$

$$\psi_{h,\sigma}^N = (0, 0, 1 + \sigma, 1 - \sigma)^T/2, \quad (9)$$

$$\psi_{e,\sigma}^S = [1 + \sigma, 1 - \sigma, (1 - \sigma)\rho\Gamma_+, (1 + \sigma)\Gamma_+]^T/2,$$

$$\psi_{h,\sigma}^S = [(1 + \sigma)\Gamma_-, (1 - \sigma)\rho\Gamma_-, 1 - \sigma, 1 + \sigma]^T/2,$$

$$\Gamma_+ = \frac{\Delta^*(\mathbf{k})}{\tilde{E} + \sqrt{\tilde{E}^2 - |\Delta(\mathbf{k})|^2}}, \quad (10)$$

$$\Gamma_- = \frac{\Delta(\tilde{\mathbf{k}})}{\tilde{E} + \sqrt{\tilde{E}^2 - |\Delta(\tilde{\mathbf{k}})|^2}}, \quad (11)$$

$$\tilde{E} = eV - \frac{H}{H_0} \Delta_0 \left( \frac{k_y}{k_F} \cos \gamma - \frac{k_x}{k_F} \sin \gamma \right), \quad (12)$$

with  $\tilde{\mathbf{k}} = (k_x, k_y, -k_z)$  and  $H_0 = \Delta_0/(e\lambda v_F)$ .  $\Delta(\mathbf{k}) = \tilde{\Delta}_{3d}^v(\mathbf{k})$ ,  $\tilde{\Delta}_{2d}^v(\mathbf{k})$ , or  $\tilde{\Delta}_{E_{1u}}^{\text{chiral}}(\mathbf{k})$ . Here,  $\rho = -1$  for  $\Delta_{3d}^{v=1}$  and  $\Delta_{2d}^{v=2}$  (even parity) and  $\rho = 1$  for  $\Delta_{3d}^{v=0,2}$ ,  $\Delta_{2d}^{v=1}$ , and  $\Delta_{E_{1u}}^{\text{chiral}}$  (odd parity).

The coefficients ( $a_{\sigma,\sigma'}, b_{\sigma,\sigma'}, c_{\sigma}, d_{\sigma}$ ) are determined by the boundary conditions:

$$\Psi_{\sigma}^N(0_-, \mathbf{k}_{\parallel}) = \Psi^S(0_+, \mathbf{k}_{\parallel}), \quad (13)$$

$$\left. \frac{d\Psi^S}{dz} \right|_{z=0_+} - \left. \frac{d\Psi_{\sigma}^N}{dz} \right|_{z=0_-} = \frac{2mU_0}{\hbar^2} \Psi_{\sigma}^N(0_-, \mathbf{k}_{\parallel}), \quad (14)$$

where the insulating barrier at  $z = 0$  is simplified as  $V(z) = U_0\delta(z)$ . The angle-resolved conductance is given by [10,51]

$$\begin{aligned} \sigma_S(eV, \mathbf{k}_{\parallel}) &= 1 + \frac{1}{2} \sum_{\sigma, \sigma' = \pm} [|a_{\sigma, \sigma'}|^2 - |b_{\sigma, \sigma'}|^2] \\ &= \sigma_N \frac{1 + \sigma_N |\Gamma_+|^2 + (\sigma_N - 1) |\Gamma_+ \Gamma_-|^2}{|1 + (\sigma_N - 1) \Gamma_+ \Gamma_-|^2}, \end{aligned} \quad (15)$$

$$\sigma_N(\mathbf{k}_{\parallel}) = \frac{4 \cos^2 \theta}{4 \cos^2 \theta + Z^2}, \quad (16)$$

with  $\cos \theta = k_z/k_F$  and  $Z = 2mU_0/(\hbar^2 k_F)$ .

In the procedure of obtaining conductance with magnetic field, we neglect the Zeeman effect. For  $\text{UPT}_3$ , the order of  $\lambda \sim 10^4 \text{ \AA}$  [55],  $k_F \sim 1 \text{ \AA}^{-1}$  [56]. Here the order of the energy of Doppler shift is  $H\Delta/H_0$  with  $H_0 = h/(2e\pi^2\xi\lambda)$  and  $\xi = \hbar^2 k_F/(\pi m \Delta)$  [26]. Since the Zeeman energy is given by  $\mu_B H$ , the ratio of the energy of Doppler shift to Zeeman effect is  $2\lambda k_F \sim 10^4$  times larger than that of Zeeman energy for  $\text{UPT}_3$ . Thus neglecting the Zeeman effect is a good approximation in present case.

In Sec. III A, we discuss SABSs with  $H = 0$ , which is determined by requiring the condition that the denominator of Eq. (15) is zero for  $Z \rightarrow \infty$  ( $\sigma_N \rightarrow 0$ ). Then, at the energy dispersion of the SABS, the denominator of Eq. (15) must satisfy following the conditions

$$\text{Re}(\Gamma_+ \Gamma_-) = 1, \quad (17)$$

$$\text{Im}(\Gamma_+ \Gamma_-) = 0. \quad (18)$$

In this case,  $\sigma_S$  becomes two, which is the maximum value of angle-resolved conductance owing to the perfect resonance. We define  $E(\mathbf{k}_{\parallel}) = \tilde{E}$ , which satisfies Eq. (17) and Eq. (18).

Here, we derive a general formula of SABS for pair potentials with arbitrary momentum dependence (details are explained in Appendix B). There are two cases. For  $\text{Im}[\Delta^*(\mathbf{k})\Delta(\tilde{\mathbf{k}})] \neq 0$ , the energy dispersion of SABS  $E(\mathbf{k}_{\parallel})$  is given by

$$E(\mathbf{k}_{\parallel}) = \frac{\text{Im}[\Delta^*(\mathbf{k})\Delta(\tilde{\mathbf{k}})]}{|\Delta(\mathbf{k}) - \Delta(\tilde{\mathbf{k}})|}, \quad (19)$$

where  $\Delta(\mathbf{k})$  and  $\Delta(\tilde{\mathbf{k}})$  must satisfy

$$\begin{aligned} &\{|\Delta(\mathbf{k})|^2 - \text{Re}[\Delta^*(\mathbf{k})\Delta(\tilde{\mathbf{k}})]\} \\ &\times \{|\Delta(\tilde{\mathbf{k}})|^2 - \text{Re}[\Delta^*(\mathbf{k})\Delta(\tilde{\mathbf{k}})]\} \geq 0. \end{aligned} \quad (20)$$

For  $\text{Im}[\Delta^*(\mathbf{k})\Delta(\tilde{\mathbf{k}})] = 0$ ,

$$E(\mathbf{k}_{\parallel}) = 0, \quad (21)$$

$$\text{with } \frac{\Delta(\mathbf{k})}{|\Delta(\mathbf{k})|} = -\frac{\Delta(\tilde{\mathbf{k}})}{|\Delta(\tilde{\mathbf{k}})|}. \quad (22)$$

This formula reproduces all of the known results of SABSs in 2D unconventional superconductors, such as  $d$ -wave [1,6],  $p$ -wave [18,21],  $d + is$ -wave [57,58], chiral  $p$ -wave [59], and chiral  $d$ -wave.

In Secs. III B and III C, we discuss the normalized conductance given by

$$\sigma(eV) = \frac{\int_{|k_x^2 + k_y^2| < k_F} dk_x dk_y \sigma_S(eV, k_x, k_y)}{\int_{|k_x^2 + k_y^2| < k_F} dk_x dk_y \sigma_N(k_x, k_y)}, \quad (23)$$

which can be measured experimentally [1].

## B. $4 \times 4$ BdG Hamiltonian

In this section, we explain the case in which the BdG Hamiltonian is in the  $4 \times 4$  form. In Sec. III C, in addition to  $\Delta_{3d}^{v=2}$  and  $\Delta_{E_{1u}}^{\text{chiral}}$ , we choose  $\Delta_{E_{1u}}^{\text{planar}}$  (Fig. 2) and  $\Delta_{E_{2u}}^{f+p}$ .  $\Delta_{E_{1u}}^{\text{planar}}$  is a spin-triplet pair potential in a unitary state, i.e.,  $\mathbf{q} = i\mathbf{d} \times \mathbf{d}^* = 0$ , while  $\Delta_{E_{2u}}^{f+p}$  can incorporate nonunitary case ( $\mathbf{q} \neq 0$ ).  $\Delta_{E_{1u}}^{\text{planar}}$  is given by

$$\Delta_{E_{1u}}^{\text{planar}}(\mathbf{k}) = \frac{\Delta_0}{r_{E_{1u}} k_F^3} (5k_z'^2 - k_F^2)(ik_x' \sigma_0 + k_y' \sigma_1). \quad (24)$$

It is noted that the time reversal symmetry is not broken for  $\Delta_{E_{1u}}^{\text{planar}}$  but  $\Delta_{E_{1u}}^{\text{chiral}}$  does not have time reversal symmetry.

$\Delta_{E_{2u}}^{f+p}$  is the combination of chiral  $p$ -wave and  $f$ -wave pairings. The  $\mathbf{d}$  vector of  $\Delta_{E_{2u}}^{f+p}$  is given by

$$\begin{aligned} \mathbf{d} &= \frac{\Delta_0}{r_{f+p}} \left\{ \delta \frac{1}{k_F} [(k_x' + i\eta k_y')d_x + i(\eta k_x' + ik_y')d_y] \right. \\ &\quad \left. + \frac{1}{k_F^3} [k_z'(k_x'^2 - k_y'^2) + 2i\eta k_z' k_x' k_y'] d_z \right\}, \end{aligned} \quad (25)$$

where  $\delta$  is considered to be small [60] and  $r_{f+p}$  is a normalized factor that is determined numerically so that the maximum value of the pair potential becomes  $\Delta_0$ . If  $(\eta, \delta) = (1, 0)$  is satisfied, we obtain  $\Delta_{E_{2u}}^{f+p} = \Delta_{3d}^{v=2}$ . The position of nodes of this  $f + p$ -wave pairing depends on the values of  $\eta$  and  $\delta$ . If  $\delta = 0$  is satisfied (Fig. 3), there are two cases. In the case of  $\eta = 0$  [Figs. 3(a-i)–3(a-iii)], there are three line nodes. For  $\eta > 0$  [Figs. 3(b-i)–3(b-iii)], there is a line node and two point nodes. For  $\delta > 0$  (Fig. 4), there are three cases. For  $\eta < 1$  [Figs. 4(a-i)–4(a-iii)], there are 16 point nodes on  $k_y = \pm k_x$  lines [Fig. 4(a-ii)]. In the case of  $\eta = 1$  [Figs. 4(b-i)–4(b-iii)], the positions of nodes are the same as that in the case of  $\eta > 0$  and  $\delta = 0$  [Figs. 3(b-i)–3(b-iii)]. For  $\eta > 1$  [Figs. 4(c-i)–4(c-iii)], there are 16 point nodes on lines  $k_x k_y = 0$ , as shown in Fig. 4(c-ii).

The wave function for the normal metal side is shown in Eq. (6) with Eqs. (8) and (9) and that for the superconducting side is given in Eq. (7) with

$$(\psi_{e,\uparrow}^S, \psi_{e,\downarrow}^S, \psi_{h,\uparrow}^S, \psi_{h,\downarrow}^S) = \begin{pmatrix} u_e & v_h \\ v_e & u_h \end{pmatrix},$$



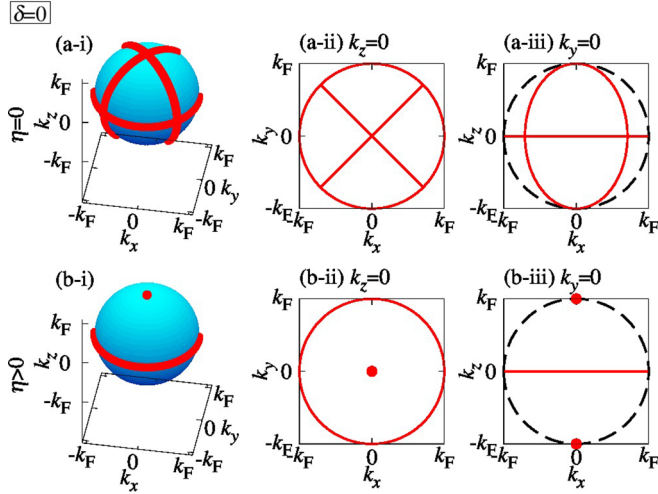


FIG. 3. Red lines and dots indicate the positions of nodes of the pair potentials  $\Delta_{E_{2u}}^{f+p}$  for  $\delta = 0$ .  $\eta = 0$  for (a-i)–(a-iii).  $\eta > 0$  for (b-i)–(b-iii). (a-ii) and (b-ii) are nodes projected on the  $k_z = 0$  plane. (a-iii) and (b-iii) are nodes projected on the  $k_y = 0$  plane. Dashed lines in (a-iii) and (b-iii) indicate projected Fermi surface on  $k_y = 0$  plane.

with

$$u_{e(h)} = \frac{[\tilde{E} + \omega_{+(-)}]\sigma_0}{\sqrt{(\tilde{E} + \omega_{+(-)})^2 + \frac{1}{2}\text{Tr}\Delta_{+(-)}\Delta_{+(-)}^\dagger}},$$

$$v_e = \frac{\Delta_+^\dagger}{\sqrt{(\tilde{E} + \omega_+)^2 + \frac{1}{2}\text{Tr}\Delta_+\Delta_+^\dagger}},$$

$$v_h = \frac{\Delta_-}{\sqrt{(\tilde{E} + \omega_-)^2 + \frac{1}{2}\text{Tr}\Delta_-\Delta_-\dagger}},$$

$$\omega_\pm = \sqrt{\tilde{E}^2 - \frac{1}{2}\text{Tr}\Delta_\pm\Delta_\pm^\dagger},$$

$$\Delta_+ = \Delta_{E_{1u}}^{\text{planar}}(\mathbf{k}),$$

$$\Delta_- = \Delta_{E_{1u}}^{\text{planar}}(\tilde{\mathbf{k}}),$$

for  $\Delta_{E_{1u}}^{\text{planar}}(\mathbf{k})$  and

$$u_e = a_+[|\mathbf{q}_+|\sigma_0 + \mathbf{q}_+ \cdot \boldsymbol{\sigma}](\sigma_0 + \sigma_3) + b_+[|\mathbf{q}_+|\sigma_0 - \mathbf{q}_+ \cdot \boldsymbol{\sigma}](\sigma_0 - \sigma_3),$$

$$u_h = a_-[|\mathbf{q}_-|\sigma_0 + \mathbf{q}_- \cdot \boldsymbol{\sigma}^*](\sigma_0 + \sigma_3) + b_-[|\mathbf{q}_-|\sigma_0 - \mathbf{q}_- \cdot \boldsymbol{\sigma}^*](\sigma_0 - \sigma_3),$$

$$a_\pm = \frac{1}{\sqrt{16|\mathbf{q}_\pm| [|\mathbf{q}_\pm| + (\mathbf{q}_\pm)_3]}} \sqrt{\frac{\tilde{E} + \omega_{\pm,p}}{\tilde{E}}},$$

$$b_\pm = \frac{1}{\sqrt{16|\mathbf{q}_\pm| [|\mathbf{q}_\pm| + (\mathbf{q}_\pm)_3]}} \sqrt{\frac{\tilde{E} + \omega_{\pm,m}}{\tilde{E}}},$$

$$v_e = \Delta_+^\dagger u_e (\tilde{E}\sigma_0 + \hat{\omega}_{+,pm})^{-1},$$

$$v_h = \Delta_- u_h (\tilde{E}\sigma_0 + \hat{\omega}_{-,pm})^{-1},$$

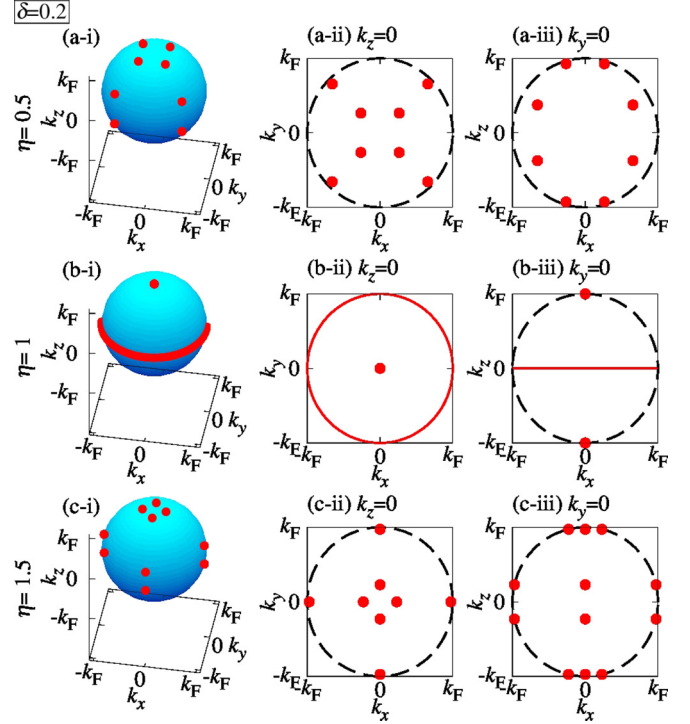


FIG. 4. Red lines and dots indicate the positions of nodes of the pair potential  $\Delta_{E_{2u}}^{f+p}$  for  $\delta = 0.2$ .  $\eta = 0.5$  for (a-i)–(a-iii).  $\eta = 1$  for (b-i)–(b-iii).  $\eta = 1.5$  for (c-i)–(c-iii). (a-ii), (b-ii), and (c-ii) are nodes projected on the  $k_z = 0$  plane. (a-iii), (b-iii), and (c-iii) are nodes projected on the  $k_y = 0$  plane. Dashed lines in (a-ii), (a-iii), (b-ii), (c-ii), and (c-iii) indicate the projected Fermi surface on the  $k_z = 0$  or  $k_y = 0$  plane.

$$\hat{\omega}_{\pm,pm} = \begin{pmatrix} \omega_{\pm,p} & 0 \\ 0 & \omega_{\pm,m} \end{pmatrix},$$

$$\omega_{\pm,p} = \sqrt{\tilde{E}^2 - (|\mathbf{d}_\pm|^2 + |\mathbf{q}_\pm|)},$$

$$\omega_{\pm,m} = \sqrt{\tilde{E}^2 - (|\mathbf{d}_\pm|^2 - |\mathbf{q}_\pm|)},$$

$$\mathbf{q}_\pm = i\mathbf{d}_\pm \times \mathbf{d}_\pm^*,$$

$$\mathbf{d}_+ = \mathbf{d}(\mathbf{k}),$$

$$\mathbf{d}_- = \mathbf{d}(\tilde{\mathbf{k}}),$$

for  $\Delta_{E_{2u}}^{f+p}$ . The boundary conditions are given in Eqs. (13) and (14). We derive a general formula for conductance, which includes the nonunitary case. This formula is similar to that derived in the context of doped topological insulators [61]. In the present case,  $\Gamma_\pm$  is available for a general pair potential, including nonunitary spin-triplet pairing. The derivation of conductance for a general pair potential is given in Appendix C:

$$\sigma_S = \frac{\sigma_N}{2} \text{Tr}[\sigma_0 - (1 - \sigma_N)\hat{\Gamma}_+^\dagger\hat{\Gamma}_+^{-1}]^{-1} \times [1 + \sigma_N\hat{\Gamma}_+^\dagger\hat{\Gamma}_+ + (\sigma_N - 1)\hat{\Gamma}_+^\dagger\hat{\Gamma}_-^\dagger\hat{\Gamma}_-^{-1}] \times [\sigma_0 - (1 - \sigma_N)\hat{\Gamma}_-\hat{\Gamma}_+^{-1}], \quad (26)$$

with

$$\hat{\Gamma}_+ = \frac{\Delta_+^\dagger}{\tilde{E} + \omega_+},$$

$$\hat{\Gamma}_- = \frac{\Delta_-}{\tilde{E} + \omega_-},$$

for  $\Delta_{E_{1u}}^{\text{planar}}$ , and

$$\begin{aligned} \hat{\Gamma}_+ &= \frac{\Delta_+^\dagger}{2} \left[ \left( \frac{1}{\tilde{E} + \omega_{+,p}} + \frac{1}{\tilde{E} + \omega_{+,m}} \right) \right. \\ &\quad \left. + \left( \frac{1}{\tilde{E} + \omega_{+,p}} - \frac{1}{\tilde{E} + \omega_{+,m}} \right) \frac{\mathbf{q}_+}{|\mathbf{q}_+|} \cdot \boldsymbol{\sigma} \right], \\ \hat{\Gamma}_- &= \frac{\Delta_-}{2} \left[ \left( \frac{1}{\tilde{E} + \omega_{-,p}} + \frac{1}{\tilde{E} + \omega_{-,m}} \right) \right. \\ &\quad \left. + \left( \frac{1}{\tilde{E} + \omega_{-,p}} - \frac{1}{\tilde{E} + \omega_{-,m}} \right) \frac{\mathbf{q}_-}{|\mathbf{q}_-|} \cdot \boldsymbol{\sigma}^* \right], \end{aligned}$$

for  $\Delta_{E_{2u}}^{f+p}$ . It is noted that the charge conductance for  $\Delta_{E_{1u}}^{\text{planar}}$  can be written by using  $\Delta_{E_{1u}}^{\text{chiral}}$ :

$$\begin{aligned} \sigma_S(eV, \mathbf{k}_\parallel) &= \frac{\sigma_N}{2} [1 + \sigma_N |\Gamma_+|^2 + (\sigma_N - 1) |\Gamma_+ \Gamma_-|^2] \\ &\quad \times \left( \frac{1}{S_1} + \frac{1}{S_2} \right), \end{aligned} \quad (27)$$

$$S_1 = \frac{1}{|1 + (\sigma_N - 1) \Gamma_+ \Gamma_-|^2}, \quad (28)$$

$$S_2 = \frac{1}{|1 + (\sigma_N - 1) \Omega_+ \Omega_-|^2},$$

$$\Omega_+ = \frac{\tilde{\Delta}_{E_{1u}}^{\text{chiral}}(\mathbf{k})}{\tilde{E} + \sqrt{\tilde{E}^2 - |\tilde{\Delta}_{E_{1u}}^{\text{chiral}}(\mathbf{k})|^2}}, \quad (29)$$

$$\Omega_- = \frac{[\tilde{\Delta}_{E_{1u}}^{\text{chiral}}(\tilde{\mathbf{k}})]^*}{\tilde{E} + \sqrt{\tilde{E}^2 - |\tilde{\Delta}_{E_{1u}}^{\text{chiral}}(\tilde{\mathbf{k}})|^2}},$$

where  $\Gamma_\pm$  in Eq. (28) is the same as in Eqs. (10) and (11) if  $\Delta$  is replaced by  $\tilde{\Delta}_{E_{1u}}^{\text{chiral}}$ . SABS is given by Eq. (17), Eq. (18), and

$$\text{Re}(\Omega_+ \Omega_-) = 1, \quad \text{Im}(\Omega_+ \Omega_-) = 0.$$

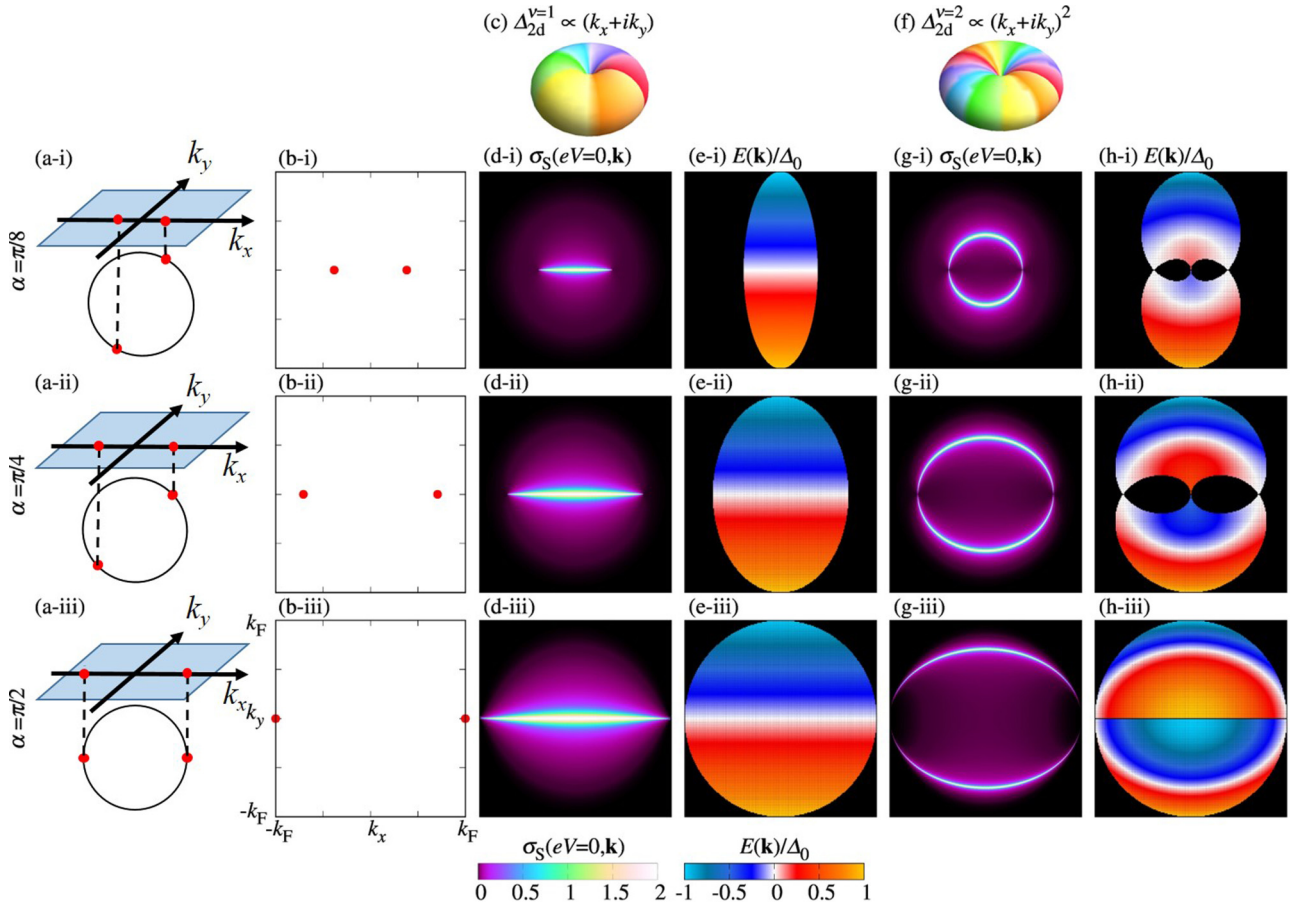


FIG. 5. Schematic illustration of point nodes (red dots) for (a-i)  $\alpha = \pi/8$ , (a-ii)  $\pi/4$ , and (a-iii)  $\pi/2$ . Point nodes projected on the  $k_x - k_y$  plane corresponding to (a-i)–(a-iii) are shown in (b-i)–(b-iii). Schematic picture of pair potential for (c)  $\Delta_{2d}^{v=1}$  and (f)  $\Delta_{2d}^{v=2}$ . The angle-resolved zero-bias conductance  $\sigma_S(eV = 0, \mathbf{k}_\parallel)$  at  $Z = 6$  are plotted as functions of  $k_x$  and  $k_y$  for  $\Delta_{2d}^{v=1}$  [(d-i)  $\alpha = \pi/8$ , (d-ii)  $\pi/4$ , and (d-iii)  $\pi/2$ ]. Similar plots for  $\Delta_{2d}^{v=2}$  for (g-i)  $\alpha = \pi/8$ , (g-ii)  $\pi/4$ , and (g-iii)  $\pi/2$ . The energy dispersions of the SABS  $E(\mathbf{k}_\parallel)$  are plotted as functions of  $k_x$  and  $k_y$  for  $\Delta_{2d}^{v=1}$  [(e-i)–(e-iii)] and for  $\Delta_{2d}^{v=2}$  [(h-i)–(h-iii)].

Owing to the presence of time reversal symmetry, the energy dispersion of the SABS is given by

$$E(\mathbf{k}_{\parallel}) = \pm E^{\text{chiral}}(\mathbf{k}_{\parallel}),$$

where  $E^{\text{chiral}}(\mathbf{k}_{\parallel})$  is the energy dispersion of the SABS for  $\Delta_{E_{1u}}^{\text{chiral}}$ . The normalized conductance is given in Eq. (23).

### C. Topological number

In this section, we briefly summarize the main discussion about the number of the ZESABSs for  $\Delta_{2d}^{\nu}$  and  $\Delta_{3d}^{\nu}$  ( $\nu \leq 2$ ) [41]. This result is used in Sec. III A. The ZESABSs for  $\Delta_{2d}^{\nu}$  are understood only from a 2D topological number (Chern number) and those for  $\Delta_{3d}^{\nu}$  are understood from a one-dimensional topological number (winding number) and the Chern number. Similar discussions for  $\Delta_{3d}^{\nu > 2}$  and  $\Delta_{E_{1u}}^{\text{chiral}}$  are given in Appendix A. For  $\Delta_{3d}^{\nu > 2}$  with  $0 < \alpha < \pi/4$ , cylindrical cuts must be used to calculate the Chern number.

Generally, if a Hamiltonian possesses time reversal symmetry, the winding number can be defined by using a chiral operator  $\Gamma = -iCT$  ( $C = \sigma_0\tau_1K$ : charge conjugation,  $T = i\sigma_2\tau_0K$ : time reversal.  $\sigma_i$  and  $\tau_i$  are the Pauli matrices in spin and Nambu spaces, respectively) which anticommutes with the Hamiltonian. The winding number is given by [8,62,63]

$$W(\mathbf{k}_{\parallel}, \Gamma) = \frac{-1}{4\pi i} \int_{-\infty}^{\infty} dk_{\perp} \text{Tr}[\Gamma H^{-1}(\mathbf{k}) \partial_{k_{\perp}} H(\mathbf{k})],$$

where  $\mathbf{k}_{\parallel}$  and  $k_{\perp}$  are wave vectors parallel and perpendicular to a certain surface, respectively. Although  $\Delta_{3d}^{\nu}$  ( $\nu \geq 1$ ) does not have time reversal symmetry, the BdG Hamiltonian hosts a momentum-dependent pseudo time reversal symmetry [41]:

$$U_{\varphi_{\mathbf{k}}}^{\dagger} T U_{\varphi_{\mathbf{k}}} H(\mathbf{k}) U_{\varphi_{\mathbf{k}}}^{\dagger} T^{\dagger} U_{\varphi_{\mathbf{k}}} = H(-\mathbf{k}),$$

with  $U_{\varphi_{\mathbf{k}}} = \exp(-i\nu\varphi_{\mathbf{k}}\sigma_0\tau_3/2)$  and  $\varphi_{\mathbf{k}} = \tan^{-1}(k_y/k_x)$ . Replacing  $\Gamma$  with  $\Gamma_{\varphi_{\mathbf{k}}}$ , we can define the winding number where  $\Gamma_{\varphi_{\mathbf{k}}}$  is given by

$$\Gamma_{\varphi_{\mathbf{k}}} = \begin{cases} U_{\varphi_{\mathbf{k}}}^{\dagger} \Gamma U_{\varphi_{\mathbf{k}}} & (\nu : \text{odd}), \\ U_{\varphi_{\mathbf{k}}}^{\dagger} S_z C T U_{\varphi_{\mathbf{k}}} & (\nu : \text{even}), \end{cases}$$

with  $S_z = \sigma_3\tau_3$ .

The Chern number [64] at a fixed  $k_{\parallel,1}$  is defined by

$$N(k_{\parallel,1}) = \frac{i}{2\pi} \sum_{n \in \text{occ}} \int_{\text{BZ}} dk_{\perp} dk_{\parallel,2} \epsilon^{ab} \partial_{k_a} \langle u_n(\mathbf{k}) | \partial_{k_b} | u_n(\mathbf{k}) \rangle,$$

where  $|u_n(\mathbf{k})\rangle$  is an eigenstate of  $H(\mathbf{k})$  and the summation is taken over all of the occupied states.

These topological numbers connect the number of the ZESABSs by the bulk-boundary correspondence. We show the angle-resolved zero voltage conductance calculated by using Eq. (15) in Fig. 5 ( $\Delta_{2d}^{\nu}$ ), Fig. 6 ( $\Delta_{3d}^{\nu=0}$ ), and Fig. 7 ( $\Delta_{3d}^{\nu=1,2}$ ). The corresponding energy dispersion of SABS calculated by using Eq. (19)–(22) are also shown in the same figures and we discuss them in Sec. III A.

The position of a line node or point nodes or both on the Fermi surface for each pair potential are shown in Figs. 5(a-i)–5(a-iii), 6(b-i)–6(b-v), and 7(a-i)–7(a-v), and those projected on the  $k_x - k_y$  (001) plane are shown in Figs. 5(b-i)–5(b-iii), 6(c-i)–6(c-v), and 7(b-i)–7(b-v). For  $\Delta_{3d}^{\nu}$ , the position of a

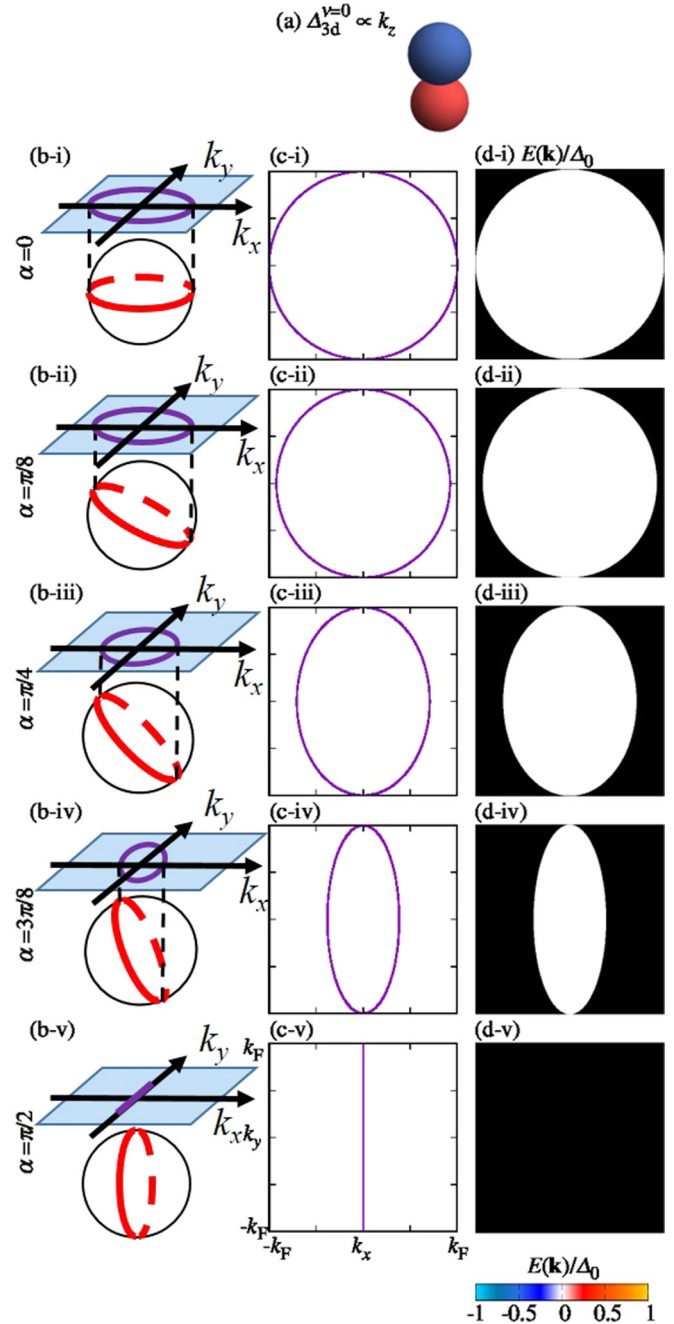


FIG. 6. Schematic illustration of pair potential for (a)  $\Delta_{3d}^{\nu=0}$ . Schematic illustration of a line node (red line) for (b-i)  $\alpha = 0$ , (b-ii)  $\pi/8$ , (b-iii)  $\pi/4$ , (b-iv)  $3\pi/8$ , and (b-v)  $\pi/2$ . The line node projected on the  $k_x$ - $k_y$  plane corresponding to (b-i)–(b-v) are shown in (c-i)–(c-v). The energy dispersion of SABS  $E(\mathbf{k}_{\parallel})$  for given  $\alpha$  are plotted as functions of  $k_x$  and  $k_y$  [(d-i)–(d-v)].

projected line node is given by

$$\frac{k_x^2}{\cos^2 \alpha} + k_y^2 = k_F^2. \quad (30)$$

The ZESABSs, including the spin degrees of freedom for  $\Delta_{3d}^{\nu=0}$ , are shown in Figs. 6(d-i)–6(d-v). The angle-resolved conductance at zero-bias voltage reflects on the ZESABSs. They are shown in Figs. 5(d-i)–5(d-iii) for  $\Delta_{2d}^{\nu}$  and



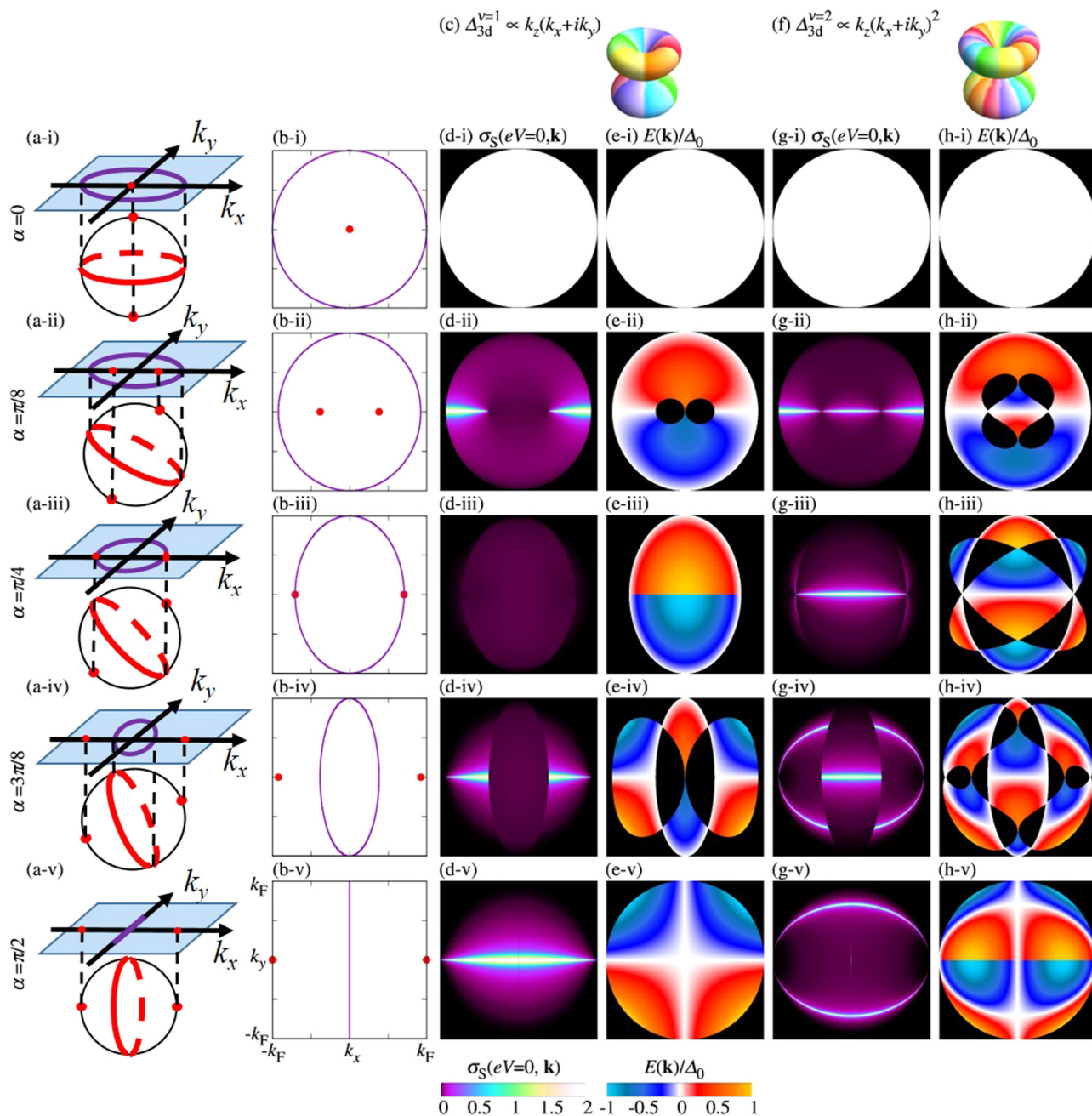


FIG. 7. Schematic illustration of point nodes (red dots) and a line node (red line) for (a-i)  $\alpha = 0$ , (a-ii)  $\pi/8$ , (a-iii)  $\pi/4$ , (a-iv)  $3\pi/8$ , and (a-v)  $\pi/2$ . Point nodes and a line node projected on the  $k_x - k_y$  plane corresponding to (a-i)–(a-v) are shown in (b-i)–(b-v). Schematic illustration of pair potential for (c)  $\Delta_{3d}^{v=1}$  and (f)  $\Delta_{3d}^{v=2}$ . The angle-resolved zero-bias conductance  $\sigma_S(eV = 0, \mathbf{k}_{\parallel})$  with  $Z = 6$  is plotted as functions of  $k_x$  and  $k_y$  for  $\Delta_{3d}^{v=1}$  [(d-i)–(d-v)] and for  $\Delta_{3d}^{v=2}$  [(g-i)–(g-v)]. The energy dispersion of the SABS  $E(\mathbf{k}_{\parallel})$  for given  $\alpha$  are plotted as functions of  $k_x$  and  $k_y$  for  $\Delta_{3d}^{v=1}$  [(e-i)–(e-v)] and for  $\Delta_{3d}^{v=2}$  [(h-i)–(h-v)].

Figs. 5(g-i)–5(g-iii) for  $\Delta_{2d}^{v=2}$ . They are also shown in Figs. 7(d-i)–7(d-v) for  $\Delta_{3d}^{v=1}$  and Figs. 7(g-i)–7(g-v) for  $\Delta_{3d}^{v=2}$ .

In the case of  $\Delta_{3d}^{v=0}$ , there are flat band SABSs within the ellipse of Eq. (30) originated from the winding number [Figs. 6(d-i)–6(d-v)]. There are two bands due to spin degrees of freedom. For  $\Delta_{3d}^{v \geq 1}$  with  $\alpha = 0$ , there are flat band SABSs within  $k_x^2 + k_y^2 \leq k_F^2$  [see Figs. 7(d-i) and 7(g-i)]. The origin of these flat bands is explained from the winding number. On the other hand, there is no ZESABS for  $\Delta_{2d}^v$  with  $\alpha = 0$  (not shown). In the case of  $\alpha = \pi/4$  for  $\Delta_{3d}^{v=1}$ , there is no ZESABS

[Fig. 7(d-iii)], while they exist on  $k_y = 0$  for  $\alpha = \pi/4$  with  $\Delta_{3d}^{v=2}$  [Fig. 7(g-iii)]. In other cases, (except for  $\alpha = 0, \pi/4$  for  $\Delta_{3d}^{v \geq 1}$  and  $\alpha = 0$  for  $\Delta_{2d}^v$ ), the number of the arc shaped ZESABSs which terminate at projected point nodes on the  $k_x$ - $k_y$  plane is  $2\nu$ , where two comes from the spin degeneracy [see Figs. 5(d-i)–5(d-iii), 5(g-i)–5(g-iii) and Figs. 7(d-ii), 7(d-iv), 7(d-v), 7(g-ii), 7(g-iv), and 7(g-v)]. For  $\Delta_{2d}^v$ , the number of ZESABSs connecting two projected point nodes is  $2\nu$ .

In addition to the ZESABSs those terminate at the projected point nodes, the ZESABSs located on  $k_y = 0$  and  $\cos \alpha > |k_x|$



TABLE I. Origin of ZESABSs for each pair potential.  $w$  and  $c$  indicate winding number and Chern number, respectively.

| $\Delta$            | $\alpha = 0$ | $0 < \alpha < \frac{\pi}{4}$ | $\alpha = \frac{\pi}{4}$ | $\frac{\pi}{4} < \alpha < \frac{\pi}{2}$ | $\alpha = \frac{\pi}{2}$ |
|---------------------|--------------|------------------------------|--------------------------|--|--------------------------|
| $\Delta_{2d}^v$     | —            | $c$                          | $c$                      | $c$                                      | $c$                      |
| $\Delta_{3d}^{v=0}$ | $w$          | $w$                          | $w$                      | $w$                                      | —                        |
| $\Delta_{3d}^{v=1}$ | $w$          | $w$                          | —                        | $c$                                      | $c$                      |
| $\Delta_{3d}^{v=2}$ | $w$          | $w$                          | $w$                      | $w$ and $c$                              | $c$                      |

appear for  $\pi/4 < \alpha \leq \pi/2$  with  $\Delta_{3d}^{v=2}$ . For  $0 < \alpha < \pi/4$  with  $\Delta_{3d}^{v=1,2}$ , the ZESABSs are originated from the winding number. For  $\pi/4 < \alpha < \pi/2$  with  $\Delta_{3d}^{v=2}$ , the ZESABSs are originated from both the winding number and the Chern number. The ZESABSs for  $\Delta_{2d}^v$  originate from the Chern number for arbitrary  $\alpha$  (Table I).

### III. RESULTS

#### A. Andreev bound state with $H = 0$

In this section, we calculate the energy dispersion of the SABS with  $H = 0$  for two cases of chiral superconductors where pair potentials are given by  $(k'_x + ik'_y)^v$  ( $v = 1, 2$ ) and  $k'_z(k'_x + ik'_y)^v$  ( $v = 1, 2$ ). Although the ZESABS has been discussed in a previous paper [41], the energy dispersion of the SABS with nonzero energy has not been clarified at all. To resolve this problem, we calculate the energy spectrum of the SABSs from Eqs. (19) to (22).

Here, we apply this formula for normal metal/3D chiral superconductor junctions. First, we calculate the energy dispersion and tunneling conductance of the 2D-like chiral superconductor, where the pair potential is given by  $\Delta_{2d}^v \propto (k'_x + ik'_y)^v$ . The angle-resolved zero-bias conductance and the energy dispersion of SABS are shown in Fig. 5. For  $v = 1$ , the angle-resolved zero voltage conductance is plotted from Figs. 5(d-i) to 5(d-iii). As explained in Sec. II C, we can see that the ZESABS appears on the line connecting two point nodes at  $k_y = 0$ . The region of the ZESABS spreads with the increase of  $\alpha$ . The corresponding energy dispersion of the SABS  $E(\mathbf{k}_{\parallel})$  is shown in Figs. 5(e-i)–5(e-iii). In this case, we can obtain an analytical formula for the SABS, given by

$$E(\mathbf{k}_{\parallel}) = -\Delta_0 k_y / k_F \quad (31)$$

$$\text{with } k_x^2 + k_y^2 \sin^2 \alpha \leq k_F^2 \sin^2 \alpha. \quad (32)$$

The number of SABSs including the zero energy state is two (including the spin degeneracy). For  $v = 2$ , two branches of the ZESABS appear as arcs on the  $k_x - k_y$  plane connecting two point nodes as shown from Figs. 5(g-i) to 5(g-iii). The length of the arcs increases with the increase of  $\alpha$ . The corresponding  $E(\mathbf{k}_{\parallel})$  is shown from Figs. 5(h-i) to 5(h-iii). The number of SABSs including zero energy state is four. Then, we can summarize that the number of SABSs stemming from topological origins, including the ZESABS, is  $2\nu$ .

Next, we focus on the case of 3D chiral superconductors [ $\Delta_{3d}^v \propto k'_z(k'_x + ik'_y)^v$ , including the  $p$ -wave case]. In the  $p$ -wave ( $v = 0$ ) case (see Fig. 6), the energy dispersion of the SABS is shown from Figs. 6(d-i) to 6(d-v). It is located

inside the ellipse given by Eq. (30) and there only appears the ZESABS.

For the  $\nu = 1$  and 2 cases, (see Fig. 7), the angle-resolved zero voltage conductance is plotted in Figs. 7(d-i)–7(d-v) for  $\nu = 1$  and the corresponding energy dispersion of the SABS  $E(\mathbf{k}_{\parallel})$  is shown in Figs. 7(e-i)–7(e-v). We can derive an analytical formula of  $E(\mathbf{k}_{\parallel})$  for  $\alpha = \pi/4$  and  $\pi/2$  given by

$$E(\mathbf{k}_{\parallel}) = -\frac{\Delta_0}{2\sqrt{2}r_{3d,v=1}} (\hat{k}_x + \sqrt{1 - \hat{k}_x^2 - \hat{k}_y^2})^2 \\ \times (\hat{k}_x - \sqrt{1 - \hat{k}_x^2 - \hat{k}_y^2}) \text{sgn}(\hat{k}_y),$$

$$\text{with } 2k_x^2 + k_y^2 \leq k_F^2,$$

where  $\hat{k}_i = k_i / k_F$  ( $i = x, y, z$ ) and

$$E(\mathbf{k}_{\parallel}) = -\frac{\Delta_0}{r_{3d,v=1}} \hat{k}_y |\hat{k}_x|,$$

respectively. The number of SABSs  $n_{\text{ABS}}$ , which includes the ZESABS, is classified by whether  $(k_x, k_y)$  is inside the ellipse [Eq. (30)] or not. Inside the ellipse,  $n_{\text{ABS}}$  becomes two (including the spin degeneracy) for  $\alpha < \pi/4$  and zero for  $\alpha \geq \pi/4$ . On the other hand, outside the ellipse,  $n_{\text{ABS}}$  becomes zero for  $\alpha \leq \pi/4$  and four for  $\alpha > \pi/4$ . Besides this SABS with topological origin, inside the ellipse, nonzero nontopologically SABS which does not include the zero-energy state exists.

Next, we focus on the  $\nu = 2$  case. Angle-resolved zero voltage conductance is plotted in Figs. 7(g-i)–7(g-v) and the corresponding energy dispersion of the SABS  $E(\mathbf{k}_{\parallel})$  is shown in Figs. 7(h-i)–7(h-v). We can derive an analytical formula of  $E(\mathbf{k}_{\parallel})$  for  $\alpha = \pi/2$  given by

$$E(\mathbf{k}_{\parallel}) = \frac{\Delta_0}{r_{3d,v=2}} \text{sgn}(\hat{k}_y) |\hat{k}_x| (1 - \hat{k}_x^2 - 2\hat{k}_y^2).$$

$n_{\text{ABS}}$  is also classified whether  $(k_x, k_y)$  is inside the ellipse or not. Inside the ellipse,  $n_{\text{ABS}}$  becomes two for  $\alpha = 0$ . For  $0 < \alpha < \pi/4$ ,  $n_{\text{ABS}}$  is four and  $n_{\text{ABS}} = 2$  for  $\alpha \geq \pi/4$ . On the other hand, outside the ellipse,  $n_{\text{ABS}}$  becomes zero for  $\alpha \leq \pi/4$  and eight for  $\alpha > \pi/4$ . Beside this SABS with topological origin, nonzero nontopologically SABSs also exist.

We further calculate  $n_{\text{ABS}}$  up to  $\nu = 4$  (The ZESABSs for  $0 < \alpha < \pi/4$  with  $\nu = 3, 4$  are discussed in Appendix A 2). A summary of  $n_{\text{ABS}}$  as a function of  $\nu$  is shown in Table II. We

TABLE II. The number of SABS ( $n_{\text{ABS}}$ ) which cross zero-energy for  $\Delta_{3d}^v$ . It is classified by inside or outside of the ellipse [Eq. (30)] corresponding to projected line node [Figs. 6(c-i)–6(c-v) and 7(b-i)–7(b-v)].  $n_{\text{ABS}}$  is counted including the spin degeneracy. The dash “—” means there is no area inside or outside the ellipse [Figs. 6(c-i) and 6(c-v)].

| $\alpha$                                 | $n_{\text{ABS}}$ |                 |
|--|------------------|-----------------|
|  | Inside ellipse   | Outside ellipse |
| 0  | 2                | —               |
| $0 < \alpha < \frac{\pi}{4}$             | $2\nu$           | 0               |
| $\alpha = \pi/4$                         | $2(\nu - 1)$     | 0               |
| $\frac{\pi}{4} < \alpha < \frac{\pi}{2}$ | $2(\nu - 1)$     | $4\nu$          |
| $\alpha = \pi/2$                         | —                | $4\nu$          |

TABLE III. The energy dispersion of SABS  $E(\mathbf{k}_{\parallel})/\Delta_0$  times normalization factor  $r$  ( $r = r_{3d,\nu}$  for  $\Delta_{3d}^{\nu}$  and  $r = 1$  for  $\Delta_{2d}^{\nu}$ ) at  $\alpha = \pi/2$  is shown for  $\Delta_{3d}^{\nu}$  and  $\Delta_{2d}^{\nu}$ .  $\hat{k}_i = k_i/k_F$  ( $i = x, y, z$ ). For the chiral 3D superconductor, the line  $k_x = 0$  does not express the energy dispersion of SABS since  $\Delta_{3d}^{\nu}(k_x = 0) = 0$  is satisfied for  $\nu = 1, 2, 3$ .

| $\Delta(\mathbf{k})$ | $E(\mathbf{k}_{\parallel})r/\Delta_0$  |
|----------------------|--|
| $k_x(-k_z + ik_y)$   | $-\hat{k}_y \hat{k}_x $  |
| $(-k_z + ik_y)$      | $-\hat{k}_y$   |
| $k_x(-k_z + ik_y)^2$ | $\text{sgn}(\hat{k}_y) \hat{k}_x (1 - \hat{k}_x^2 - 2\hat{k}_y^2)[48]$                             |
| $(-k_z + ik_y)^2$    | $\text{sgn}(\hat{k}_y)(1 - \hat{k}_x^2 - 2\hat{k}_y^2)$  |
| $k_x(-k_z + ik_y)^3$ | $- \hat{k}_x \hat{k}_y(3 - 3\hat{k}_x^2 - 4\hat{k}_y^2)\text{sgn}(1 - \hat{k}_x^2 - 2\hat{k}_y^2)$ |
| $(-k_z + ik_y)^3$    | $-\hat{k}_y(3 - 3\hat{k}_x^2 - 4\hat{k}_y^2)\text{sgn}(1 - \hat{k}_x^2 - 2\hat{k}_y^2)$            |

can also obtain the analytical formula of  $E(\mathbf{k}_{\parallel})$  both for the 3D and 2D-like chiral superconductors for  $\alpha = \pi/2$ . The results are summarized in Table III.

### B. Conductance with magnetic field

In this section, we discuss the magnetic field dependence of conductance. We consider the situation in which a magnetic field is applied in the  $x$ - $y$  plane [Eq. (5)] and is rotated along the  $z$  axis by  $\gamma$  (Fig. 8). It is known that the applied magnetic field shifts the energy of quasiparticle as a Doppler effect [26]. In the usual case, ZBCP without a magnetic field is split into two [26,54] or the height of ZBCP is suppressed [20,65] by the Doppler effect. For chiral  $p$ -wave superconductors, the height of ZBCP is controlled by the direction of the applied magnetic field [65]. In contrast to this standard knowledge, we show a unique behavior whereby the Doppler effect can change the line shape of conductance from zero-bias dip to zero-bias peak, as shown in Fig. 9 ( $\Delta_{3d}^{\nu=1}$ ) and Fig. 11 ( $\Delta_{3d}^{\nu=2}$ ).

For  $\alpha = \pi/8$  with  $H = 0$  [Figs. 9(f) and 11(f)],  $\sigma$  near  $eV = 0$  has a concave shape, and it changes into ZBCP for  $H/H_0 = 0.1$  with  $\gamma = \pi$  [Figs. 9(c) and 11(c)]. The Doppler effect shifts the energy dispersion of the SABS along the vector  $(\cos \gamma, \sin \gamma, 0)$ , as shown in Fig. 8. The SABS that is slightly above or below zero energy for  $H = 0$  can contribute to zero-bias conductance in the presence of the magnetic field. For  $\nu = 1$ , in Fig. 9(e), there is no ZESABS. However, in the presence of the magnetic field for  $\gamma = \pi$ , a SABS exists around zero energy near  $(k_x, k_y) = (0, \pm k_F)$  [Fig. 9(b)]. We can also see the

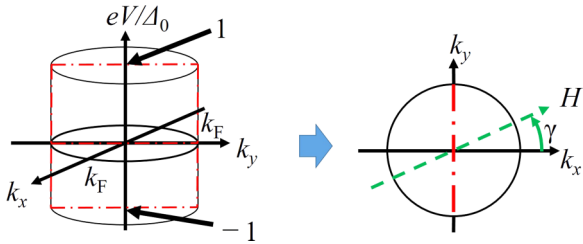


FIG. 8. Dash dotted line (red line) represents a rectangular located at  $k_y/k_F = [-1, 1]$  and  $eV/\Delta_0 = [-1, 1]$  on  $k_y - eV$  plane which are used for (b), (e), and (h) in Figs. 9, 11, and 13. Dashed line (green line) represents the direction of magnetic field which corresponds to the arrow in Fig. 1.

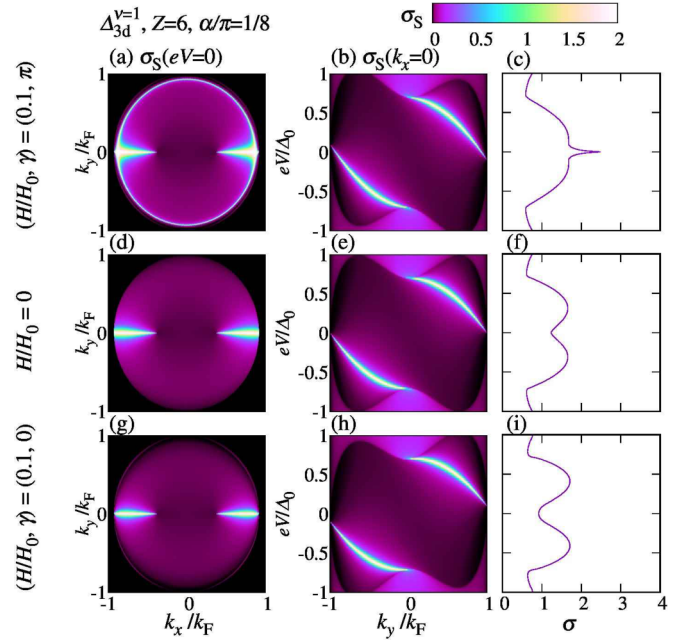


FIG. 9. Angle-resolved conductance  $\sigma_S(eV, \mathbf{k}_{\parallel})$  for  $\Delta_{3d}^{\nu=1}$  with  $\alpha = \pi/8$  are plotted as functions of  $(k_x, k_y)$  with  $eV = 0$  [(a), (d), and (g)] and  $(k_y, eV)$  with  $k_x = 0$  [(b), (e), and (h)] (see Fig. 8) and normalized conductance plotted as a function of  $eV$  [(c), (f), and (i)]. Normalized magnetic field  $H/H_0$  is chosen to be 0.1 with  $\gamma = \pi$  [(a), (b), and (c)], 0 [(d), (e), and (f)], 0.1 with  $\gamma = 0$  [(g), (h), and (i)].

circle near  $k_x^2/\cos^2(\pi/8) + k_y^2 = k_F^2$  of ZESABS in Fig. 9(a), which does not exist in Fig. 9(d). On the other hand, in the case that the direction of the magnetic field is opposite, i.e.,  $\gamma = 0$ , SABS around zero energy remains absent [Figs. 9(g) and 9(h)]. As seen from Fig. 9(a), the angle-resolved conductance near  $(k_x, k_y) = (\pm k_F, 0)$  is enhanced. In Fig. 10(a), we can see how the ZBCP develops with increasing magnetic field. We can see the generation of ZBCP even for small magnitudes of  $H$  with  $H/H_0 = 0.01$ . The magnitude of zero-bias conductance as a function of  $H$  is shown in Fig. 10(b) and it is approximately a linear function of  $H$ .

A similar plot for  $\nu = 2$  with the same  $\alpha$  is shown in Fig. 11. In this case, in contrast to Fig. 9, chiral edge mode crossing  $k_y = 0$  exists [see Figs. 7(h-ii) and 11(e)]. There

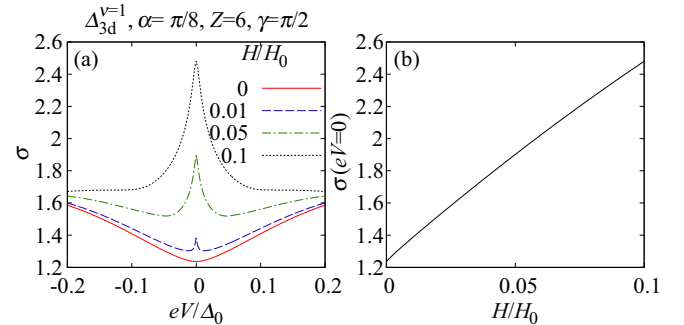


FIG. 10. (a) Conductance is plotted as a function of  $eV$  for  $H/H_0 = 0, 0.01, 0.05,$  and  $0.1$  with  $\gamma = \pi/2$ . (b) Conductance at  $eV = 0$  is plotted as a function of  $H/H_0$ . This plot is fitted by the linear function  $f(H/H_0) = aH/H_0 + b$  with  $(a, b) = (12.4, 1.27)$ .

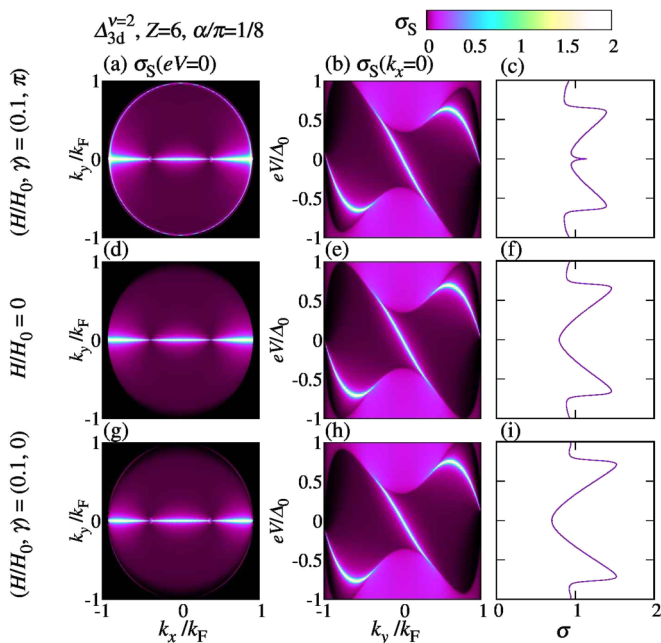


FIG. 11. Angle-resolved conductance of  $\Delta_{3d}^{\nu=2}$  with  $\alpha = \pi/8$ . The model parameters used in this calculation is the same as in Fig. 9 except for pair potential  $\Delta$ .

are two kinds of branches of SABS: (1) chiral edge mode crossing  $(k_x, k_y) = (0, 0)$  and (2) SABS touching the ellipse given by  $k_x^2/\cos^2(\pi/8) + k_y^2 = k_F^2$ . The slope of the chiral edge mode becomes gradual (steep) for  $\gamma = 0$  ( $\gamma = \pi$ ) in the presence of the magnetic field. The contribution to zero-bias conductance becomes suppressed (enhanced) for  $\gamma = \pi$  ( $\gamma = 0$ ). On the other hand, the qualitative feature of SABS touching the ellipse is similar to that for  $\nu = 1$  shown in Fig. 9. In the presence of the magnetic field for  $\gamma = \pi$ , ZESABS exists near  $(k_x, k_y) = (\pm k_F, 0)$  and around the ellipse [Fig. 11(a)]. Since the contribution to zero-bias conductance from SABS touching the ellipse is dominant as compared to that of the chiral edge mode, the resulting  $\sigma$  has a ZBCP. On the other hand, if the direction of the magnetic field is opposite, ZBCP is absent [Fig. 11(i)]. In Fig. 12(a), we show how ZBCP develops with increasing magnetic field. Even for small magnitude of  $H$  ( $H/H_0 = 0.01$ ), ZBCP appears similar to Fig. 10(a). The

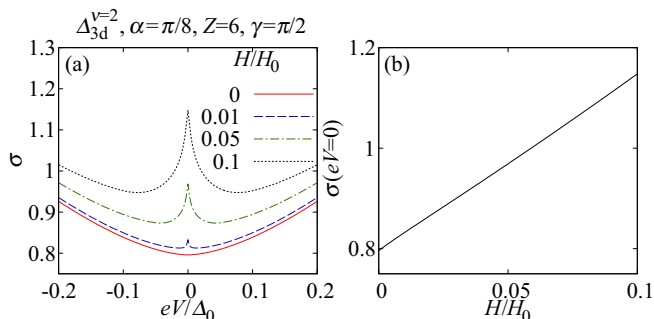


FIG. 12. (a) Conductance is plotted as a function of  $eV$  for  $H/H_0 = 0, 0.01, 0.05$ , and  $0.1$  with  $\gamma = \pi/2$ . (b) Conductance at  $eV = 0$  is plotted as a function of  $H/H_0$ . This plot is fitted by the linear function  $f(H/H_0) = aH/H_0 + b$  with  $(a, b) = (3.49, 0.796)$ .

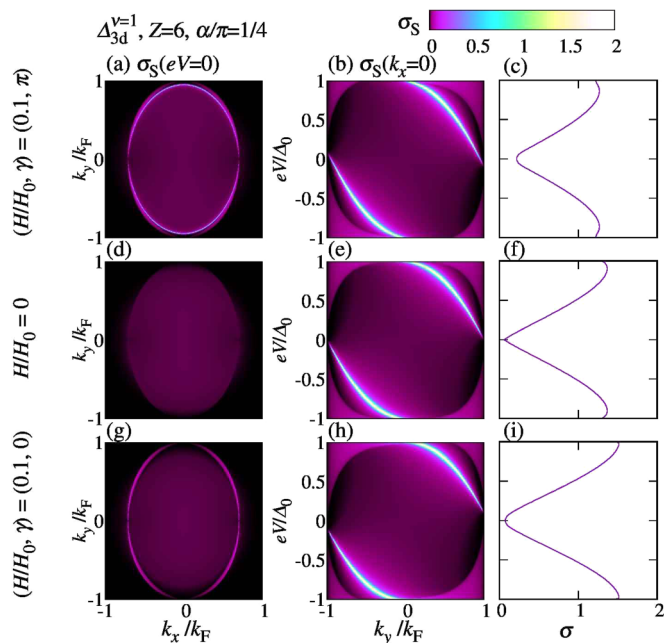


FIG. 13. Angle-resolved conductance of  $\Delta_{3d}^{\nu=1}$  with  $\alpha = \pi/4$ . The parameters are the same as Fig. 9 except for  $\alpha$ .

magnitude of conductance at zero bias as a function of  $H$  is shown in Fig. 12(b) and it is an approximately linear function of  $H$ . The slope  $a$  of the fitting function  $f(H/H_0) = aH/H_0 + b$  is smaller than that for  $\Delta_{3d}^{\nu=1}$ .

Next, let us discuss special case of  $\Delta_{3d}^{\nu=1}$  for  $\alpha = \pi/4$ , at which there is no ZESABS without magnetic field [Fig. 7(d-iii)]. The magnitude of the zero-bias conductance for  $H = 0$  is very small [Fig. 13(f)] and it becomes larger for  $\gamma = \pi$  [Fig. 13(c)] due to the similar mechanism explained in Fig. 9. For  $\gamma = 0$  [Fig. 13(i)], although there is no SABS at zero-energy, the conductance becomes slightly larger than that for  $H = 0$ .

Whether the magnitude of ZBCP becomes larger or smaller by applying an infinitesimally small magnitude of magnetic field is summarized in Table IV. For 2D-like chiral superconductors with  $\nu = 1$ , since the energy dispersion of the SABS is given by  $E(\mathbf{k}_{\parallel}) = -k_y/k_F$  [Eqs. (31) and (32)], the magnitude of  $\sigma(eV = 0)$  becomes larger for  $\gamma = 0$  and smaller for  $\gamma = \pi$ . In other cases, there is no simple law owing to the complicated energy dispersion of the SABS. Using this table, we can classify five cases. If we make a junction for  $\alpha = \pi/2$ , we can distinguish between  $\nu = 0$  ( $k'_z$ ),  $\nu = 1$  [ $k'_z(k'_x + ik'_y)$ ,  $(k'_x + ik'_y)$ ], and  $\nu = 2$  [ $k'_z(k'_x + ik'_y)^2$ ,  $(k'_x + ik'_y)^2$ ]. Further, if we make a junction for  $\alpha = 0$ , we can distinguish between  $k'_z(k'_x + ik'_y)^{\nu}$  and  $(k'_x + ik'_y)^{\nu}$  with  $(\nu = 1, 2)$ .

To clarify the  $\gamma$  dependence of the conductance, we plot  $\sigma(eV = 0)$  as a function of  $\gamma$  for  $\alpha = \pi/4$ , and  $\pi/2$  in Fig. 14. For  $\alpha = 0$ ,  $\sigma(eV = 0)$  is constant as a function of  $\gamma$  owing to the rotational symmetry of the pair potentials (not shown). Since  $\Delta_{3d}^{\nu=0}$  conserves time reversal symmetry, i.e., the energy dispersion of the SABS has twofold rotational symmetry [Figs. 6(d-i)–6(d-v)],  $\sigma$  has  $\pi$  periodicity [Figs. 14(b) and 14(c)]. In other cases,  $\sigma(eV = 0)$  has  $2\pi$  periodicity due to time reversal symmetry breaking.



TABLE IV. Line shape of  $\sigma(eV)$  near  $eV = 0$  for  $H = 0$ . p: peak, d: dip. Whether the magnitude of  $\sigma(eV = 0)$  is enhanced (suppressed) by the magnetic field is indicated by  $\uparrow$  ( $\downarrow$ ). We choose the infinitesimal applied magnetic field as  $H/H_0 = 10^{-4}$ . In the case  $\Delta \propto k'_z$ , the values of  $\sigma(eV = 0)$  at  $H > 0$  with  $\gamma = 0$  and  $\gamma = \pi$  are equivalent because  $\sigma$  is a  $\pi$  periodic function of  $\gamma$ .

| $\Delta(\mathbf{k})$   | $H/H_0$   | $\gamma$ | $\alpha$     |              |              |              |              |
|------------------------|-----------|----------|--------------|--------------|--------------|--------------|--------------|
|                        |           |          | 0            | $\pi/8$      | $\pi/4$      | $3\pi/8$     | $\pi/2$      |
| $k'_z$                 | 0         | -        | p            | p            | p            | p            | d            |
|                        | $10^{-4}$ | $0, \pi$ | $\downarrow$ | $\downarrow$ | $\downarrow$ | $\downarrow$ | $\uparrow$   |
| $k'_z(k'_x + ik'_y)$   | 0         | -        | p            | d            | d            | d            | p            |
|                        | $10^{-4}$ | 0        | $\downarrow$ | $\downarrow$ | $\uparrow$   | $\uparrow$   | $\uparrow$   |
|                        | $10^{-4}$ | $\pi$    | $\downarrow$ | $\uparrow$   | $\uparrow$   | $\downarrow$ | $\downarrow$ |
| $(k'_x + ik'_y)$       | 0         | -        | d            | d            | p            | p            | p            |
|                        | $10^{-4}$ | 0        | $\uparrow$   | $\uparrow$   | $\uparrow$   | $\uparrow$   | $\uparrow$   |
|                        | $10^{-4}$ | $\pi$    | $\downarrow$ | $\downarrow$ | $\downarrow$ | $\downarrow$ | $\downarrow$ |
| $k'_z(k'_x + ik'_y)^2$ | 0         | -        | p            | d            | d            | p            | d            |
|                        | $10^{-4}$ | 0        | $\downarrow$ | $\downarrow$ | $\uparrow$   | $\uparrow$   | $\downarrow$ |
|                        | $10^{-4}$ | $\pi$    | $\downarrow$ | $\uparrow$   | $\downarrow$ | $\downarrow$ | $\uparrow$   |
| $(k'_x + ik'_y)^2$     | 0         | -        | d            | p            | p            | d            | d            |
|                        | $10^{-4}$ | 0        | $\uparrow$   | $\uparrow$   | $\uparrow$   | $\downarrow$ | $\downarrow$ |
|                        | $10^{-4}$ | $\pi$    | $\uparrow$   | $\downarrow$ | $\downarrow$ | $\uparrow$   | $\uparrow$   |

The values of  $\gamma$  that maximize  $\sigma(eV = 0)$  are summarized in Table V. In the case of  $\Delta_{3d}^{v=0}$  with  $\alpha = \pi/2$ ,  $\sigma(eV = 0)$  becomes the smallest when the direction of the magnetic field is parallel to the direction of the projected line node. This result is consistent with that for the 2D  $d$ -wave case [54,66]. However, in the case of 3D chiral superconductors with  $\Delta_{3d}^{v=1,2}$ , this does not hold.

### C. Symmetry of pairing potential of UPT<sub>3</sub>

Recently, the guide to determine the pairing symmetry of UPT<sub>3</sub> by using quasiparticle interference in a slab model was theoretically proposed [67]. However, the role of the SABS in determining the charge transport in junctions has not yet been revealed. We also propose a way to determine the pairing symmetry by using a Doppler shift. In this section, we consider  $\Delta_{3d}^{v=2}$ ,  $\Delta_{E_{1u}}^{\text{chiral}}$ , and  $\Delta_{E_{1u}}^{\text{planar}}$  as candidates of the pairing symmetry.

The crystal symmetry of UPT<sub>3</sub> is  $P6_3/mmc$ , so the pair potential around the  $\Gamma$  point respects  $D_{6h}$ . In addition, various experiments [46] indicate a spin-triplet pairing and coexistence of point and line nodes.  $\Delta_{3d}^{v=2}$  and  $\Delta_{E_{1u}}^{\text{planar}}$  satisfy these properties and are possible candidates for the pairing symmetry of UPT<sub>3</sub> [68].  $\Delta_{E_{1u}}^{\text{chiral}}$  does not have time reversal symmetry and  $\Delta_{E_{1u}}^{\text{planar}}$  has time reversal symmetry. For  $\Delta_{E_{1u}}^{\text{planar}}$ , the conductance is given by Eq. (27).

Firstly, let us discuss the SABS of  $\Delta_{E_{1u}}^{\text{chiral}}$  and  $\Delta_{E_{1u}}^{\text{planar}}$  (Fig. 15). The positions of point and line nodes are shown on the Fermi surface for  $\alpha = \pi/8$  [Figs. 15(a-i)],  $\alpha = \pi/4$  [Figs. 15(a-ii)],  $\alpha = 3\pi/8$  [Figs. 15(a-iii)], and  $\alpha = \pi/2$  [Figs. 15(a-iv)]. The corresponding projected point and line nodes on the  $k_x - k_y$  plane are replotted from Figs. 15(b-i) to 15(b-iv). In the case of  $\Delta_{E_{1u}}^{\text{planar}}$ , as explained in Sec. II B, the energy dispersion of the SABS for  $\Delta_{E_{1u}}^{\text{planar}}$  is  $\pm E^{\text{chiral}}(\mathbf{k})$ .

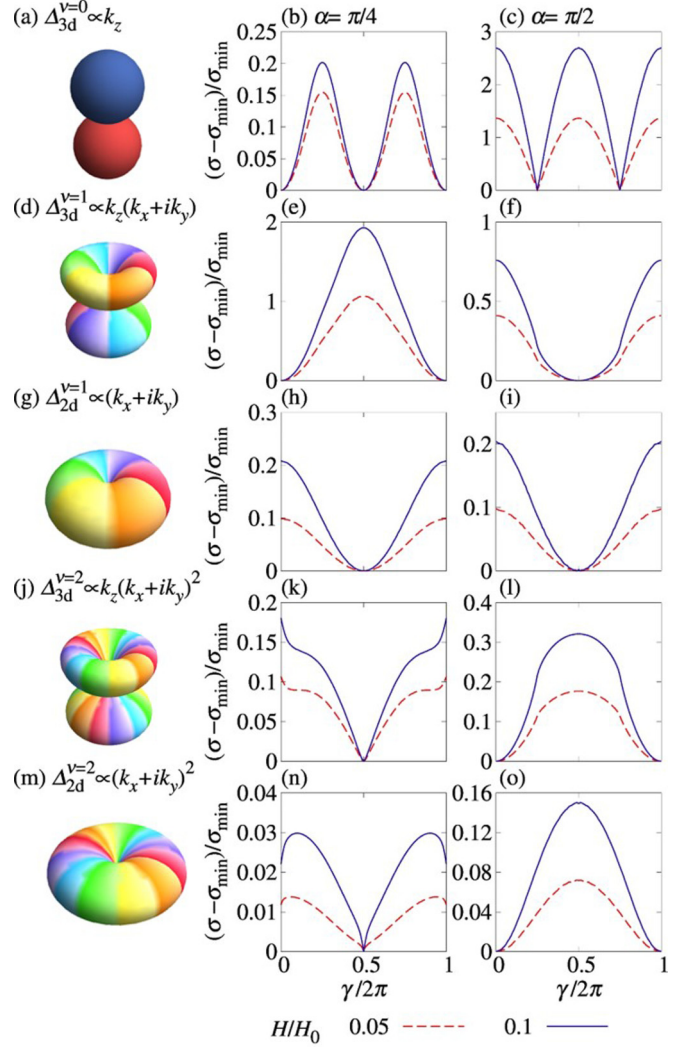


FIG. 14. Normalized conductance at  $eV = 0$  is plotted as a function of  $\gamma$  for  $v = 0, 1, 2$  with  $Z = 6$ . Schematic pictures of the pair potential are shown in (a), (d), (g), (j), and (m).  $\alpha = \pi/4$  for (b), (e), (h), (k), and (n).  $\alpha = \pi/2$  for (c), (f), (i), (l), and (o).  $\sigma_{\min}$  is a minimum value of  $\sigma(eV = 0)$  as a function of  $\gamma$  for  $H/H_0 = 0.05$  and  $H/H_0 = 0.1$ .

For example, Fig. 15(e-i) is the same as Figs. 15(h-i), and Figs. 15(h-i) and 15(i-i) are the energy dispersions of the SABS for  $\Delta_{E_{1u}}^{\text{planar}}$ . Owing to the presence of two line nodes, there is no SABS at  $\alpha = 0$  for either  $\Delta_{E_{1u}}^{\text{chiral}}$  or  $\Delta_{E_{1u}}^{\text{planar}}$  (not shown). For

TABLE V.  $\gamma$  at which  $\sigma(eV = 0)$  becomes maximum as a function of  $\gamma$  with  $H/H_0 = 0.1$ .

| $\Delta$               | $\alpha$        |                 |                 |          |
|------------------------|-----------------|-----------------|-----------------|----------|
|                        | $\pi/8$         | $\pi/4$         | $3\pi/8$        | $\pi/2$  |
| $k'_z$                 | $\pi/2, 3\pi/2$ | $\pi/2, 3\pi/2$ | $\pi/2, 3\pi/2$ | $0, \pi$ |
| $k'_z(k'_x + ik'_y)$   | $\pi$           | $\pi$           | 0               | 0        |
| $(k'_x + ik'_y)$       | $\pi$           | 0               | $\pi$           | 0        |
| $k'_z(k'_x + ik'_y)^2$ | $\pi$           | 0               | 0               | $\pi$    |
| $(k'_x + ik'_y)^2$     | $\sim 0$        | $\sim 0$        | $\pi$           | $\pi$    |



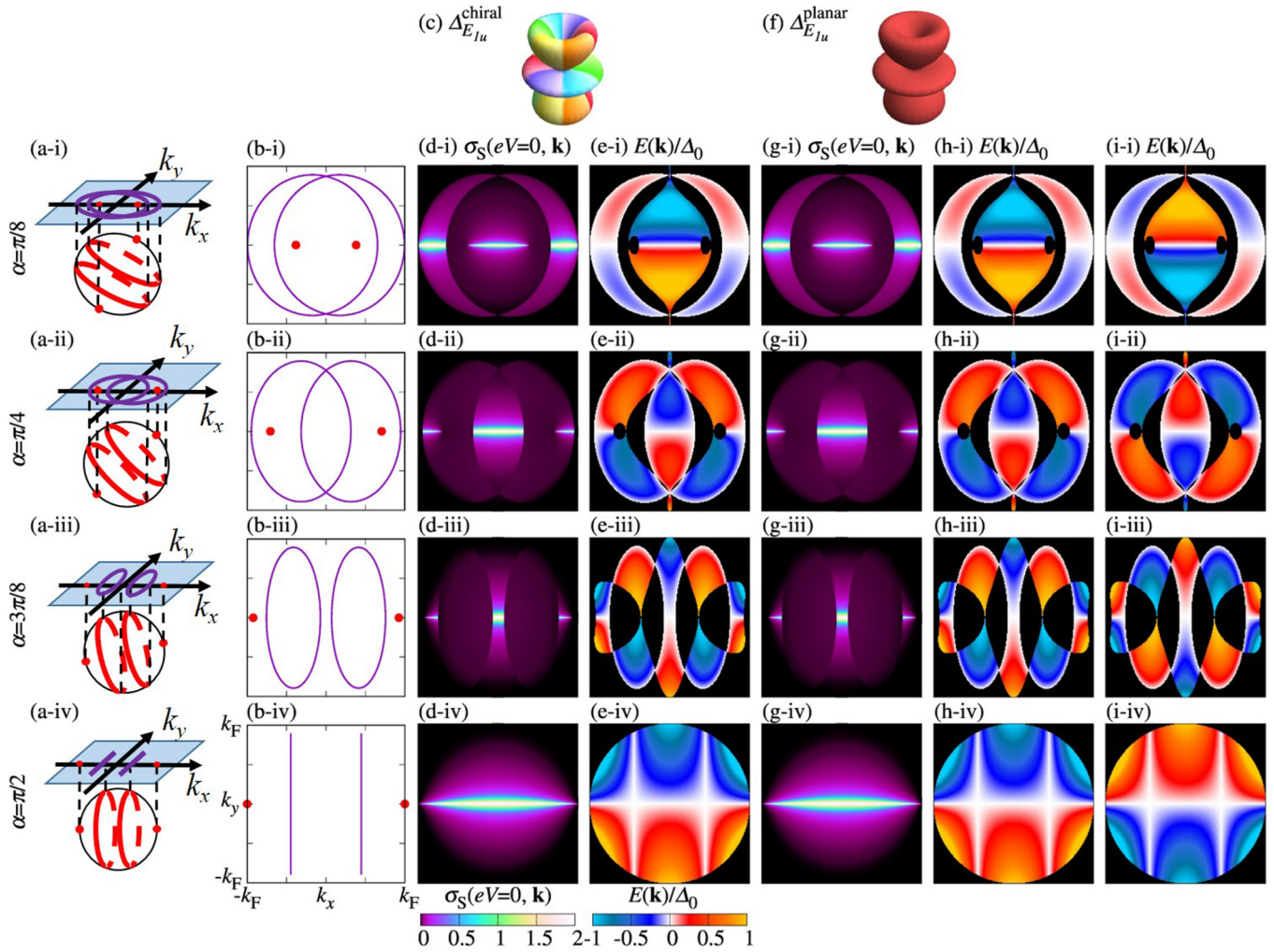


FIG. 15. Schematic illustration of point nodes (red dots) and line nodes (red lines) for (a-i)  $\alpha = \pi/8$ , (a-ii)  $\pi/4$ , (a-iii)  $3\pi/8$  and (a-iv)  $\pi/2$ . Point nodes and line nodes projected on  $k_x$ - $k_y$  plane corresponding to (a-i)–(a-iv) are shown in (b-i)–(b-iv). Schematic picture of the pair potential for (c)  $\Delta_{E_{1u}}^{\text{chiral}}$  and (f)  $\Delta_{E_{1u}}^{\text{planar}}$ . Angle-resolved zero-bias conductance  $\sigma_S(eV = 0, \mathbf{k}_{\parallel})$  with  $Z = 6$  is plotted as a function of  $k_x$  and  $k_y$  for  $\Delta_{E_{1u}}^{\text{chiral}}$  [(d-i)–(d-iv)] and for  $\Delta_{E_{1u}}^{\text{planar}}$  [(g-i)–(g-iv)]. The energy dispersion of SABS  $E(\mathbf{k}_{\parallel})$  for given  $\alpha$  is plotted as a function of  $k_x$  and  $k_y$  for  $\Delta_{E_{1u}}^{\text{chiral}}$  [(e-i)–(e-iv)] and for  $\Delta_{E_{1u}}^{\text{planar}}$  [(h-i) and (i-i)–[(h-iv) and (i-iv)].

$\alpha > 0$ , ZESABS of  $\Delta_{E_{1u}}^{\text{chiral}}$  [Figs. 15(d-i)–15(d-iv)] and that of  $\Delta_{E_{1u}}^{\text{planar}}$  [Figs. 15(g-i)–15(g-iv)] are the same because  $S_1 = S_2$  [Eqs. (28) and (29)]. The number of ZESABSs is discussed in Appendix A 1.

The energy dispersion of the SABS becomes very complicated as seen from Figs. 15(e-i) to 15(e-iv) for  $\Delta_{E_{1u}}^{\text{chiral}}$  and from Figs. 15(h-i) and 15(i-i) to Figs. 15(h-iv) and 15(i-iv) for  $\Delta_{E_{1u}}^{\text{planar}}$ . This is due to the presence of two line nodes and two

point nodes. The energy dispersion of the SABS at  $\alpha = \pi/2$  is summarized in Table VI.

The conductance for  $\Delta_{3d}^{\nu=2}$ ,  $\Delta_{E_{1u}}^{\text{chiral}}$ , and  $\Delta_{E_{1u}}^{\text{planar}}$  is shown in Fig. 16. Although the angle-resolved conductance ( $\sigma_S$ ) of  $\Delta_{E_{1u}}^{\text{planar}}$  has a counterpropagating mode in addition to the same chiral edge mode shown in  $\Delta_{E_{1u}}^{\text{chiral}}$ , the angular averaged conductance ( $\sigma$ ) is the same [Fig. 16(b)]. Therefore we can distinguish  $\Delta_{3d}^{\nu=2}$  from  $(\Delta_{E_{1u}}^{\text{chiral}}, \Delta_{E_{1u}}^{\text{planar}})$  by conductance but we cannot distinguish between  $\Delta_{E_{1u}}^{\text{chiral}}$  and  $\Delta_{E_{1u}}^{\text{planar}}$ .

To distinguish  $\Delta_{E_{1u}}^{\text{chiral}}$  from  $\Delta_{E_{1u}}^{\text{planar}}$ , we discuss the directional dependence of the magnetic field on the conductance (Fig. 17). Because  $\Delta_{E_{1u}}^{\text{chiral}}$  ( $\Delta_{E_{1u}}^{\text{planar}}$ ) does not have (has) time reversal symmetry,  $\sigma(eV = 0)$  has  $2\pi$  ( $\pi$ ) periodicity. The difference in conductance as a function of  $eV$  with  $H = 0$  and that of  $\gamma$  with the magnetic field between  $\Delta_{3d}^{\nu=2}$ ,  $\Delta_{E_{1u}}^{\text{chiral}}$ , and  $\Delta_{E_{1u}}^{\text{planar}}$  are summarized in Table VII. Whether ZBCP becomes larger or smaller when an infinitesimal magnitude

TABLE VI. The energy dispersion of SABS  $E(\mathbf{k}_{\parallel})r_{E_{1u}}/\Delta_0$  at  $\alpha = \pi/2$  is shown for  $\Delta_{E_{1u}}^{\text{chiral}}(\mathbf{k})$  and  $\Delta_{E_{1u}}^{\text{planar}}(\mathbf{k})$ .  $\hat{k}_i = k_i/k_F$  ( $i = x, y, z$ ).

| $\Delta(\mathbf{k})$                          | $E(\mathbf{k}_{\parallel})r_{E_{1u}}/\Delta_0$ |
|---|--|
| $\Delta_{E_{1u}}^{\text{chiral}}(\mathbf{k})$ | $-\hat{k}_y  5\hat{k}_x^2 - 1 $                |
| $\Delta_{E_{1u}}^{\text{planar}}(\mathbf{k})$ | $\pm \hat{k}_y  5\hat{k}_x^2 - 1 $             |

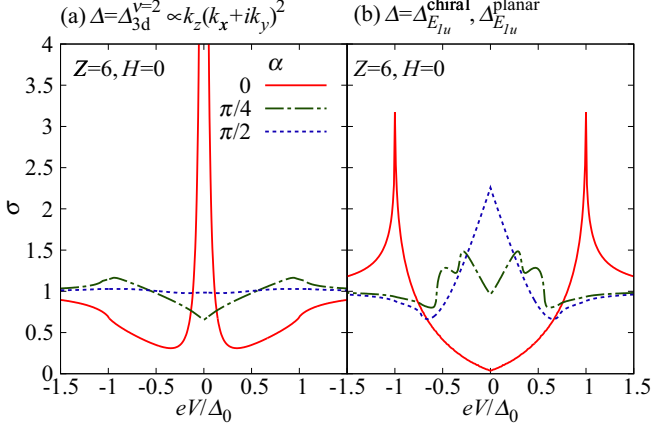


FIG. 16. Normalized conductance for spin-triplet  $f$ -wave symmetry as a function of  $eV$  for  $\alpha = 0$  (solid line),  $\pi/4$  (dash-dotted line), and  $\pi/2$  (dotted line). (a)  $\Delta_{3d}^{v=2}$  and (b)  $\Delta_{E_{1u}}^{\text{chiral}}$ ,  $\sigma$  of  $\Delta_{E_{1u}}^{\text{planar}}$  coincides with that of  $\Delta_{E_{1u}}^{\text{chiral}}$ .

of the magnetic field is applied is summarized in Table VIII and  $\gamma$  which makes conductance largest is summarized in Table IX.

Recently, Y. Yanase has proposed an extended version of  $E_{2u}$  symmetry [60] as a model of the pairing symmetry of  $\text{UPT}_3$ . It is a linear combination of the spin-triplet  $p$  and  $f$ -wave pairings. It is interesting to clarify whether the obtained results in Table VII are changed by the disappearance of a line node by the mixing of a small magnitude of chiral  $p$ -wave pair potential and  $\Delta_{3d}^{v=2}$ . We consider the nonunitary pair potential given by Eq. (25). For this purpose, we have used a general formula for tunneling conductance Eq. (26) derived in Appendix C. For  $\eta = 1$ , the obtained conductance is shown in Fig. 18. In this case, there remain two point nodes and a line node [Figs. 3(b-i)–3(b-iii) and 4(b-i)–4(b-iii)]. When nonzero  $\delta$  is introduced, ZBCP splits, but the shape of conductance is still distinct from that of  $E_{1u}$  symmetry [Fig. 16(b)]. For fixed  $\delta$ , the line shape of conductance  $\sigma$  does not change qualitatively with the change of  $\eta$  [Figs. 19(a) and 19(b)]. Hence it is expected that if the spin-triplet  $p$ -wave pair potential is additionally introduced into  $\Delta_{3d}^{v=2}$ ,  $E_{1u}$  and the extended version of  $E_{2u}$  can be distinguished by tunneling conductance.

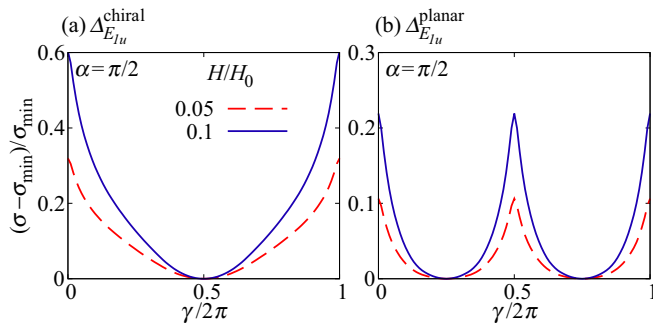


FIG. 17. Normalized conductance at  $Z = 6$  as a function of  $\gamma$  with  $\alpha = \pi/2$ .  $H/H_0 = 0.1$  (solid line) and  $0.05$  (dashed line). (a)  $\Delta_{E_{1u}}^{\text{chiral}}$  and (b)  $\Delta_{E_{1u}}^{\text{planar}}$ .

TABLE VII. Position of conductance peak with  $(\alpha, H) = (0, 0)$  (Fig. 16) and period of  $\sigma(eV = 0)$  as a function of  $\gamma$  with  $\alpha = \pi/2$  in the presence of the magnetic field [Figs. 14(I) and 17].

|                            | $\Delta_{3d}^{v=2}$ | $\Delta_{E_{1u}}^{\text{chiral}}$ | $\Delta_{E_{1u}}^{\text{planar}}$ |
|----------------------------|---------------------|-----------------------------------|-----------------------------------|
| Conductance peak           | $eV = 0$            | $eV = \Delta_0$                   | $eV = \Delta_0$                   |
| Period of $\sigma(\gamma)$ | $2\pi$              | $2\pi$                            | $\pi$                             |

#### IV. DISCUSSION AND CONCLUSION

In this paper, we have studied the surface Andreev bound state (SABS) and quasiparticle tunneling spectroscopy of three-dimensional (3D) chiral superconductors by changing the misorientation angle of superconductors. We have analytically derived a formula of the energy dispersion of SABS available for general pair potentials when an original  $4 \times 4$  matrix of BdG Hamiltonian can be decomposed into two blocks of  $2 \times 2$  matrices. We apply this formula to calculate the SABS for 3D chiral superconductors, where the pair potential is given by  $\Delta_0 k_z (k_x + ik_y)^v / k_F^{v+1}$  ( $v = 1, 2$ ). The SABS has a complex momentum dependence, owing to the coexistence of point and line nodes. The number of branches of the energy dispersion of SABS with topological origin can be understood based on the winding and Chern numbers. We have calculated the tunneling conductance of normal-metal/insulator/chiral-superconductor junctions in the presence of the applied magnetic field, which induces a Doppler shift. In contrast to previous studies of Doppler effect on tunneling conductance, a zero-bias conductance dip can change into a zero-bias conductance peak by applying the magnetic field. This unique feature originates from the complicated energy dispersion of the SABS. We have also studied the SABS and tunneling conductance of  $\text{UPT}_3$  focusing on four possible candidates of the pairing symmetry:  $E_{2u}$ ,  $E_{1u}$ -planar,  $E_{1u}$ -chiral, and extended version of  $E_{2u}$  pairings. Since the last pairing is nonunitary, we have developed a conductance formula, which is available for a general pair potential. By using this formula, we have shown that these four pairings can be identified by tunneling spectroscopy both with and without magnetic field. Thus, our theory serves as a guide to determine the pairing symmetry of  $\text{UPT}_3$ .

TABLE VIII. Line shape of  $\sigma(eV)$  near  $eV = 0$  with  $H = 0$ . p: peak, d: dip. Whether the magnitude of  $\sigma(eV = 0)$  is enhanced (suppressed) by the magnetic field indicated by  $\uparrow$  ( $\downarrow$ ). We choose the infinitesimal magnitude of the magnetic field as  $H/H_0 = 10^{-4}$ . The value of  $\sigma(eV)$  for  $\Delta_{E_{1u}}^{\text{planar}}$  at  $\gamma = 0$  and  $\gamma = \pi$  are equivalent because  $\sigma$  is a  $\pi$  periodic function of  $\gamma$ .

| $\Delta(\mathbf{k})$              | $H/H_0$   | $\gamma$ | $\alpha$   |              |            |              |              |
|-----------------------------------|-----------|----------|------------|--------------|------------|--------------|--------------|
|                                   |           |          | 0          | $\pi/8$      | $\pi/4$    | $3\pi/8$     | $\pi/2$      |
| $\Delta_{E_{1u}}^{\text{chiral}}$ | 0         | -        | d          | d            | d          | d            | p            |
|                                   | $10^{-4}$ | 0        | $\uparrow$ | $\downarrow$ | $\uparrow$ | $\uparrow$   | $\uparrow$   |
|                                   | $10^{-4}$ | $\pi$    | $\uparrow$ | $\uparrow$   | $\uparrow$ | $\downarrow$ | $\downarrow$ |
| $\Delta_{E_{1u}}^{\text{planar}}$ | 0         | -        | d          | d            | d          | d            | p            |
|                                   | $10^{-4}$ | $0, \pi$ | $\uparrow$ | $\uparrow$   | $\uparrow$ | $\uparrow$   | $\uparrow$   |

TABLE IX. The position of  $\gamma$  at which  $\sigma(eV = 0)$  becomes maximum as a function of  $\gamma$ .

| $\Delta$                          | $\alpha$ |          |          |          |
|-----------------------------------|----------|----------|----------|----------|
|                                   | $\pi/8$  | $\pi/4$  | $3\pi/8$ | $\pi/2$  |
| $\Delta_{E_{1u}}^{\text{chiral}}$ | $\pi$    | 0        | 0        | 0        |
| $\Delta_{E_{1u}}^{\text{planar}}$ | $0, \pi$ | $0, \pi$ | $0, \pi$ | $0, \pi$ |

In this paper, we are focusing on SABS and quasiparticle tunneling spectroscopy. As a next step, it will be interesting to calculate the Josephson effect in chiral superconductors, including spin-triplet nonunitary pairings [69], where both point and line nodes exist. Especially, it is known from the studies of  $d$ -wave superconductors, the role of  $\alpha$  induces non-monotonic temperature dependence of maximum Josephson current [70–73]. The study of such a kind of exotic temperature dependence of the Josephson current will be really interesting.

In this paper, we have studied the case where a normal metal is ballistic. It is a challenging issue to extend our theory to diffusive normal metal (DN)/superconductor junctions where penetration of the Cooper pair owing to the proximity effect modifies the total resistance of the junctions [74,75]. In particular, it is known that the anomalous proximity effect with zero energy peak of the local density of states in DN via odd-frequency pairing occurs in spin-triplet superconductor junctions [76–82]. An extension of previous two-dimensional studies to three dimensions is also promising.

In the remainder, we discuss points related to the conductance formula [Eq. (26) or (C16)]. (i) Doppler shift. Although the Doppler shift approximation is not quantitatively perfect, it is useful for the classification of pairing symmetry [27]. When the penetration depth is much larger than the coherence length of the superconductor, this approximation does work as far as we are discussing surface Andreev bound states and inner-gap tunneling conductance. This approximation has been

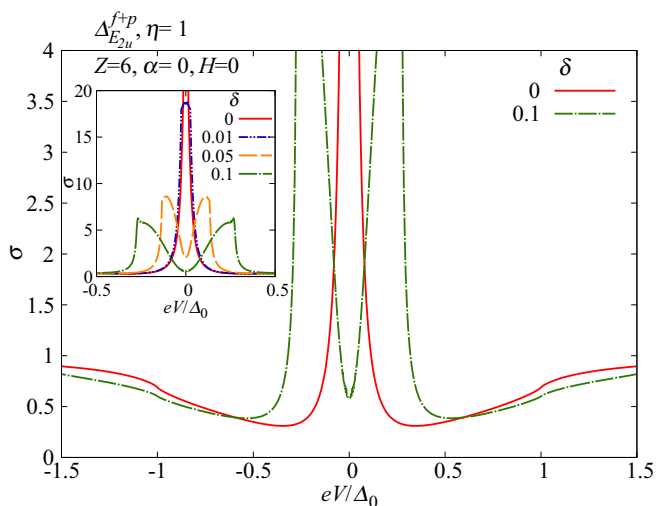


FIG. 18. Normalized conductance  $\sigma$  by its value in the normal state for  $\Delta_{E_{2u}}^{f+p}$  is plotted as a function of  $eV$  for several  $\delta$  with  $\eta = 1$  and  $Z = 6$ . Inset is the magnification near  $eV = 0$ .

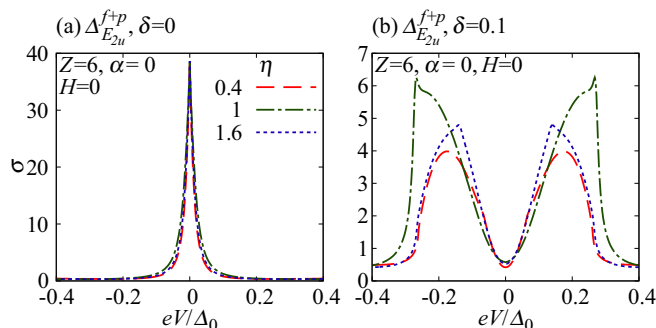


FIG. 19. Normalized conductance  $\sigma$  by its value in normal state for  $\Delta_{E_{2u}}^{f+p}$  is plotted as a function of  $eV$  for several  $\eta$  with  $Z = 6$ . (a)  $\delta = 0$  and (b) 0.1.

actually done in the previous work in Eilenberger equation [65] and qualitatively reasonable results are obtained. Also, these results are qualitatively same as the results obtained by extended version of BTK theory [20].

(ii) Isotropic Fermi surface. In the point of view of the relation between topological invariant and surface Andreev bound state (SABS), the essential feature of SABS is determined by the node structure of the pair potential in momentum space and the symmetry of the Hamiltonian when the magnitude of the pair potential is much smaller than the Fermi energy. Thus the qualitative nature of SABS is not so sensitive to the band structure. In the case that an actual Fermi surface is not topologically equivalent to the single isotropic Fermi surface, we must calculate SABS with the Fermi surface. For  $\text{UPT}_3$ , as far as superconducting pairing is formed on the Fermi surface nearest to the  $\Gamma$  point, it is expected that the qualitative shape of SABS in our paper can be compared to experimental results.

On the other hand, the line shape of the tunneling conductance is more or less influenced by band structures. When the obtained SABS has a flat band dispersion, the tunneling conductance has a zero-bias conductance peak (ZBCP) shown by the previous studies of the tight-binding model [83]. On the other hand, when the SABS has a linear dispersion like a chiral  $p$ -wave superconductor, the resulting line shape of the tunneling conductance depends on band structures [84].

As regards  $\text{UPT}_3$ , the energy band structures are complex. However, we think that one can design the experiment to greatly reduce such effect. For example, one can choose a kind of material belonging to  $\text{UPT}_3$  family or with similar band structures as a normal side. As a result, the tunneling characteristic would depend mainly on the nodal structure of the superconducting gap instead of the anisotropy of the continuous energy band. The superconducting gap structure will play a dominant role in the tunneling spectroscopy which this paper is focused on.

(iii) Applicability. If we focus on the low-energy physics and the effective Hamiltonian of the material has a single Fermi surface, the conductance formula can be useful to discuss the qualitative nature of superconductors. Especially to three-dimensional superconductors, which have complex nodes, for example, heavy Fermion compounds [85].



## ACKNOWLEDGMENTS

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## APPENDIX A: TOPOLOGICAL NUMBERS

The 3D chiral superconductors host both a winding number and a Chern number relevant to ZESABSs. In a previous study, two of the present authors have discussed relevant topological numbers in 3D chiral superconductors with  $\Delta_{3d}^{\nu=1}$  and  $\Delta_{3d}^{\nu=2}$  by taking into account an additional symmetry [41]. At this point, we explain topological numbers in 3D chiral superconductors with  $\Delta_{E_{1u}}^{\text{chiral}}$  and  $\Delta_{3d}^{\nu>2}$ .

1. Winding number in the case  $\Delta_{E_{1u}}^{\text{chiral}}$ 

Following the discussion in Ref. [41], a winding number is defined in a similar way to the case  $\Delta_{3d}^{\nu=2}$ . However,  $\Delta_{E_{1u}}^{\text{chiral}}$  has two line nodes and is an even function of  $k_z$ , leading to a vanishing of zero-energy flat band for  $\alpha = 0$ . Thus, in the following, we consider a winding number for  $\alpha \neq 0$  and  $k_y = 0$ . In the  $k_x - k_z$  plane,  $\Delta_{E_{1u}}^{\text{chiral}}$  is real, so we can define the winding number using time reversal symmetry and spin-rotation symmetry:

$$W(k_x) \equiv \frac{-1}{4\pi i} \int_{-\infty}^{\infty} dk_z \text{Tr}[\Gamma H^{-1}(\mathbf{k}) \partial_{k_z} H(\mathbf{k})]_{k_y=0}, \quad (\text{A1})$$

where  $H(\mathbf{k})$  is the BdG Hamiltonian with  $\epsilon(\mathbf{k}) = \frac{\hbar^2}{2m}(\mathbf{k}^2 - k_F^2)$  and  $\Delta_{E_{1u}}^{\text{chiral}}$ . The chiral operator, which anticommutes with  $H(\mathbf{k})$ , is given by  $\Gamma = -\sigma_1 \tau_2$ , where  $\sigma_\mu$  and  $\tau_\mu$  ( $\mu = 0, 1, 2, 3$ ) are the identity matrix and the Pauli matrices in the spin and Nambu spaces, respectively. Furthermore, using the weak pairing assumption, Eq. (A1) is reduced into

$$W(k_x) = \sum_{\epsilon(\mathbf{k})=0} \text{sgn}[\partial_{k_z} \epsilon(\mathbf{k})] \cdot \text{sgn}[(5k_z'^2 - k_F^2)k_x'], \quad (\text{A2})$$

where  $k_x' = k_x \cos \alpha - k_z \sin \alpha$  and  $k_z' = k_x \sin \alpha + k_z \cos \alpha$  and the summation is taken for  $k_z$  satisfying  $\epsilon(\mathbf{k}) = 0$ .

To evaluate the winding number (A2), we define the characteristic angles:  $\alpha_1 = \tan^{-1}(\frac{2}{\sqrt{5}+1})$ ,  $\alpha_2 = \tan^{-1}(\frac{2}{\sqrt{5}-1})$ , and  $\alpha_3 = \tan^{-1}(2)$  and the positions of point and line nodes projected onto the  $k_x$  line in the (001) plane:  $k_1^{\text{line}} = \frac{k_F}{\sqrt{5}}(\sin \alpha + 2 \cos \alpha)$  and  $k_2^{\text{line}} = \frac{k_F}{\sqrt{5}}(-\sin \alpha + 2 \cos \alpha)$  for the line nodes and  $k^{\text{point}} = k_F \sin \alpha$  for the point nodes (see Fig. 20). These angles satisfy  $0 < \frac{\pi}{8} < \alpha_1 < \frac{\pi}{4} < \alpha_2 < \alpha_3 < \frac{3\pi}{8} < \frac{\pi}{2}$ . Calculating Eq. (A2), we obtain the winding number as follows:

$$(1) 0 < \alpha \leq \alpha_1$$

$$W(k_x) = \begin{cases} 2 & -k_1^{\text{line}} < k_x < -k_2^{\text{line}} \\ -2 & -k^{\text{point}} < k_x < k^{\text{point}} \\ 2 & k_2^{\text{line}} < k_x < k_1^{\text{line}} \\ 0 & \text{otherwise} \end{cases}.$$

$$(2) \alpha_1 < \alpha \leq \alpha_2$$

$$W(k_x) = \begin{cases} 2 & -k_1^{\text{line}} < k_x < -k^{\text{point}} \\ -2 & -k_2^{\text{line}} < k_x < k_2^{\text{line}} \\ 2 & k^{\text{point}} < k_x < k_1^{\text{line}} \\ 0 & \text{otherwise} \end{cases}.$$

$$(3) \alpha_2 < \alpha \leq \alpha_3$$

$$W(k_x) = \begin{cases} -2 & -k^{\text{point}} < k_x < -k_1^{\text{line}} \\ -2 & -k_2^{\text{line}} < k_x < k_2^{\text{line}} \\ -2 & k_1^{\text{line}} < k_x < k^{\text{point}} \\ 0 & \text{otherwise} \end{cases}.$$

$$(4) \alpha_3 < \alpha \leq \frac{\pi}{2}$$

$$W(k_x) = \begin{cases} -2 & -k^{\text{point}} < k_x < -k_1^{\text{line}} \\ 2 & k_2^{\text{line}} < k_x < -k_2^{\text{line}} \\ -2 & k_1^{\text{line}} < k_x < k^{\text{point}} \\ 0 & \text{otherwise} \end{cases}.$$

The factor 2 comes from the spin degrees of freedom. The obtained results are consistent with the ZESABSs in Fig. 15.

2. Chern number in the case  $\Delta_{3d}^{\nu>2}$ 

In 3D chiral superconductors with  $\Delta_{3d}^{\nu=1}$  and  $\Delta_{3d}^{\nu=2}$ , ZESABSs are understood from both the winding number and the Chern number. On the other hand, 3D chiral superconductors with  $\Delta_{3d}^{\nu>2}$  have the redundant ZESABSs for  $0 < \alpha \leq \frac{\pi}{4}$ . To understand this type of ZESABSs, we introduce the Chern number defined on a cylinder:

$$N = \frac{i}{2\pi} \sum_{n \in \text{occ}} \int_{-\infty}^{\infty} dk_z \int_0^{2\pi} \rho d\theta \epsilon^{ab} \partial_{k_a} \langle u_n(\mathbf{k}) | \partial_{k_b} | u_n(\mathbf{k}) \rangle, \quad (\text{A3})$$

where the cylindrical coordinate is defined by  $(\rho \cos \theta \pm k_F \sin \alpha, \rho \sin \theta, k_z)$ ,  $|u_n(\mathbf{k})\rangle$  is an eigenstate of  $H(\mathbf{k})$ , and the summation is taken over all of occupied states. We choose  $\rho$  in such a way that the cylinder includes a single-point node and does not touch the line node. Then, Eq. (A3) gives  $\pm 2\nu$  in analogy with the Chern number on the  $k_y - k_z$  plane [41], where 2 comes from the spin degrees of freedom. The nontrivial Chern number predicts  $2\nu$  ZESABSs terminated at the point nodes. As shown in Figs. 7(d-ii) and 7(g-ii), single and double ZESABSs terminated at the point nodes appear on the  $k_x$  line, respectively. For  $\nu > 2$ , we find  $2\nu$  ZESABSs terminated at the point nodes [Figs. 21(d) and 21(g)]. Note that the winding number also exists and explains ZESABSs in the  $k_x$  line.



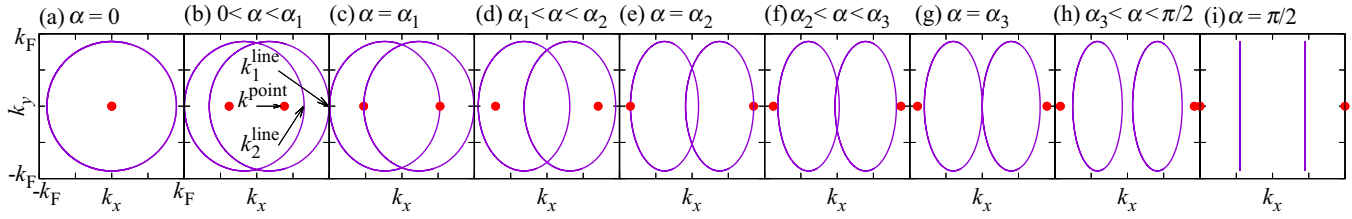


FIG. 20. The position of point nodes and line nodes for  $\Delta_{E_{1u}}^{\text{chiral}}$  projected on the  $k_x - k_y$  plane are shown for (a)  $\alpha = 0$ , (b)  $0 < \alpha < \alpha_1$ , (c)  $\alpha = \alpha_1$ , (d)  $\alpha_1 < \alpha < \alpha_2$ , (e)  $\alpha = \alpha_2$ , (f)  $\alpha_2 < \alpha < \alpha_3$ , (g)  $\alpha = \alpha_3$ , (h)  $\alpha_3 < \alpha < \pi/2$  and (i)  $\alpha = \pi/2$ . (b), (d), (h), and (i) are the same as Figs. 15(b-i), 15(b-ii), 15(b-iii), and 15(b-iv), respectively.  $k_1^{\text{line}}$ ,  $k_2^{\text{line}}$ , and  $k^{\text{point}}$  for  $0 < \alpha < \alpha_1$  are shown in (b).

### APPENDIX B: SABS

In Appendix B, we show how to derive the SABS. Since  $|\Gamma_{\pm}| = 1$  [ $\Gamma_{\pm}$  is given by Eqs. (10) and (11)] is satisfied in in-gap state, we introduce  $\theta_{\pm}$  as follows:

$$E = |\Delta_+| \cos \theta_+, \quad (\text{B1})$$

$$= |\Delta_-| \cos \theta_-. \quad (\text{B2})$$

with  $\Delta_+ = \Delta(\mathbf{k})$ ,  $\Delta_- = \Delta(\tilde{\mathbf{k}})$ . Since  $\theta_+$  and  $\theta_-$  are not independent, we obtain

$$\kappa \frac{\cos \theta_+}{\cos \theta_-} = 1, \quad (\text{B3})$$

with

$$\kappa = \frac{|\Delta_+|}{|\Delta_-|}.$$

$\theta_+$  ( $\theta_-$ ) is used for the definition of  $\Gamma_+$  ( $\Gamma_-$ ) and is confined in the domain  $0 \leq \theta_{\pm} \leq \pi$ . Then,  $\Gamma_{\pm}$  is given by

$$\Gamma_+ = \exp[i(-\phi_+ - \theta_+)],$$

$$\Gamma_- = \exp[i(\phi_- - \theta_-)],$$

where  $\phi_{\pm}$  is defined by  $\Delta_{\pm} = |\Delta_{\pm}| \exp(i\phi_{\pm})$ . Then, the SABS satisfies the following conditions:

$$0 = \text{Im}\Gamma_+\Gamma_- = \sin(\phi - \theta_+ - \theta_-), \quad (\text{B4})$$

$$1 = \text{Re}\Gamma_+\Gamma_- = \cos(\phi - \theta_+ - \theta_-), \quad (\text{B5})$$

with

$$\phi = -\phi_+ + \phi_-.$$

From Eqs. (B4) and (B5), the relation between  $\phi$  and  $\theta_{\pm}$  is obtained,

$$\phi - \theta_+ - \theta_- = -2n\pi, \quad (\text{B6})$$

$$\Leftrightarrow \theta_+ + \theta_- = 2n\pi + \phi,$$

where  $n$  is an integer. The dispersion relation is given by Eqs. (B1) and (B6) or Eqs. (B2) and (B6).

In order to eliminate  $\theta_-$ , substitute Eq. (B6) for Eq. (B3). Then, we get

$$\cos \theta_+(\kappa - \cos \phi) = \sin \theta_+ \sin \phi, \quad (\text{B7})$$

$$\Rightarrow \cos^2 \theta_+[(\kappa - \cos \phi)^2 + \sin^2 \phi] = \sin^2 \phi.$$

(I)  $\phi = 2m\pi$  ( $m$ : integer) with  $\kappa = 1$ .

( $\theta_+$ ,  $\theta_-$ )  $\neq$  ( $\pi/2$ ,  $\pi/2$ ) is satisfied by Eq. (B6). From Eq. (B3), we obtain

$$\cos \theta_+ = \cos \theta_-.$$

This condition is held with  $(\theta_+, \theta_-) = (0, 0)$  or  $(\pi, \pi)$ . However, from Eqs. (B1) or (B2),  $E = \pm|\Delta_+| = \pm|\Delta_-|$  is

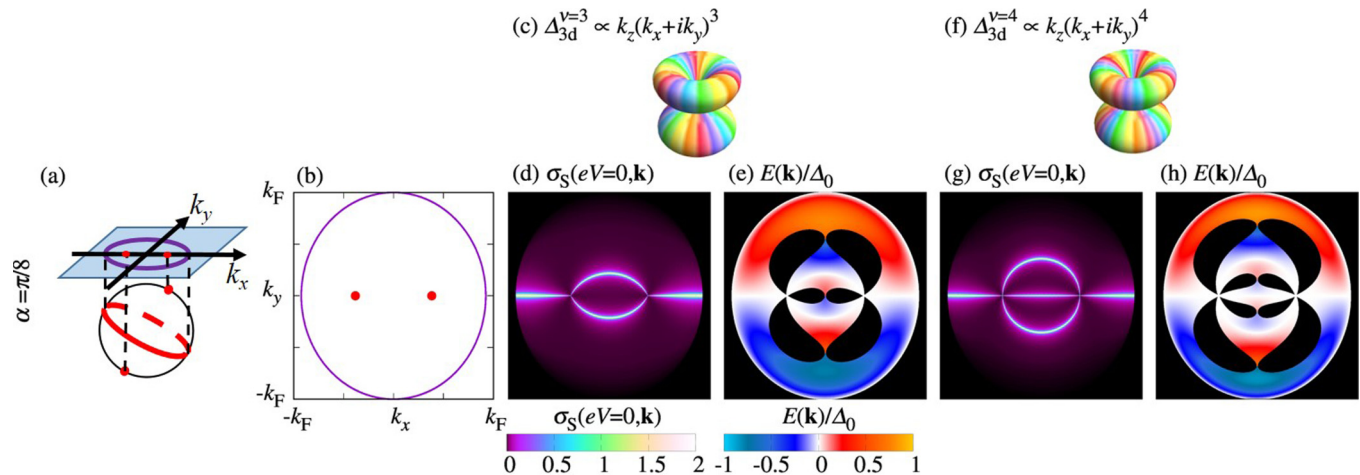


FIG. 21. (a) Schematic illustration of point nodes (red dots) and a line node (red line) for  $\alpha = \pi/8$ . Point nodes and a line node projected on the  $k_x - k_y$  plane corresponding to (a) are shown in (b). Schematic picture of pair potential for (c)  $\Delta_{3d}^{v=3} \propto k_z(k_x + ik_y)^3$  and (f)  $\Delta_{3d}^{v=4} \propto k_z(k_x + ik_y)^4$ . (d) The angle-resolved zero-bias conductance  $\sigma_S(eV=0, \mathbf{k})$  at  $Z = 6$  are plotted as functions of  $k_x$  and  $k_y$  for (d)  $\Delta_{3d}^{v=3}$  and (g)  $\Delta_{3d}^{v=4}$ . The energy dispersions of the SABS  $E(\mathbf{k}_{||})$  are plotted as functions of  $k_x$  and  $k_y$  for  $\Delta_{3d}^{v=3}$  (e) and for  $\Delta_{3d}^{v=4}$  (h).

satisfied. This means that the obtained energy dispersion is not inside the energy gap and is not the SABS (in-gap state).

(II)  $\phi \neq 2m\pi$  or  $\kappa \neq 1$ .

From Eq. (B7), we obtain  $\cos \theta_{\pm}$  and  $\sin \theta_{\pm}$  as follows:

$$\cos \theta_+ = \pm \frac{\sin \phi}{\sqrt{(\kappa - \cos \phi)^2 + \sin^2 \phi}}, \quad (\text{B8})$$

$$\sin \theta_+ = \frac{|\kappa - \cos \phi|}{\sqrt{(\kappa - \cos \phi)^2 + \sin^2 \phi}}, \quad (\text{B9})$$

$$\cos \theta_- = \pm \frac{\sin \phi}{\sqrt{(\kappa^{-1} - \cos \phi)^2 + \sin^2 \phi}}, \quad (\text{B10})$$

$$\sin \theta_- = \frac{|\kappa^{-1} - \cos \phi|}{\sqrt{(\kappa^{-1} - \cos \phi)^2 + \sin^2 \phi}}, \quad (\text{B11})$$

where the sign of  $\cos \theta_+$  and  $\cos \theta_-$  are the same. We must check whether four equations from Eq. (B8) to Eq. (B11) are consistent with Eq. (B6) or not. From Eq. (B6), we obtain the following relations:

$$\sin(\theta_+ + \theta_-) = \sin \phi,$$

$$\begin{aligned} &\Leftrightarrow \pm \sin \phi (|\kappa - \cos \phi| + |\kappa^{-1} - \cos \phi|) \\ &= \sin \phi \sqrt{(\kappa - \cos \phi)^2 + \sin^2 \phi} \sqrt{(\kappa^{-1} - \cos \phi)^2 + \sin^2 \phi}, \end{aligned} \quad (\text{B12})$$

$$\cos(\theta_+ + \theta_-) = \cos \phi,$$

$$\begin{aligned} &\Leftrightarrow \sin^2 \phi - |\kappa - \cos \phi| |\kappa^{-1} - \cos \phi| \\ &= \cos \phi \sqrt{(\kappa - \cos \phi)^2 + \sin^2 \phi} \sqrt{(\kappa^{-1} - \cos \phi)^2 + \sin^2 \phi}. \end{aligned} \quad (\text{B13})$$

From Eq. (B12), we must consider following four cases.

(II-1)  $\sin \phi = 0$ .

(i)  $\phi = 2l\pi$  ( $l$ : integer).

Substituting  $\phi = 2l\pi$  for Eq. (B13); the left-hand side of Eq. (B12) is negative but the right-hand side of it is positive. Therefore there is no SABS.

(ii)  $\phi = (2l - 1)\pi$  ( $l$ : integer).

$\phi = (2l - 1)\pi$  satisfies Eq. (B13). From Eq. (B6), we obtain

$$\theta_+ + \theta_- = \pi.$$

This equation contradicts the fact that the sign of  $\cos \theta_+$  is equal to that of  $\cos \theta_-$  except for  $\theta_{\pm} = \pi/2$ . Only for  $\theta_+ = \theta_- = \pi/2$ , we obtain

$$\frac{\Delta_+}{|\Delta_+|} = -\frac{\Delta_-}{|\Delta_-|}.$$

This is the condition known for zero-energy SABS in unconventional superconductors [1,10],

(II-2)  $\sin \phi \neq 0$ .

Hereafter, we suppose  $\kappa \leq 1$ . In the case of  $\kappa > 1$ , the same discussion can be held with replacing  $\kappa$  by  $\kappa^{-1}$ .

(i)  $\kappa - \cos \phi \geq 0$ .

In this case, Eq. (B12) becomes

$$\begin{aligned} \pm(\kappa + \kappa^{-1} - 2 \cos \phi) &= \sqrt{(\kappa - \cos \phi)^2 + \sin^2 \phi} \\ &\times \sqrt{(\kappa^{-1} - \cos \phi)^2 + \sin^2 \phi}. \end{aligned}$$

The case of the negative sign of the left-hand side does not satisfy the above equation. If we choose positive sign, it is not difficult to confirm that the above equation is always satisfied.

On the other hand, Eq. (B13) becomes

$$\begin{aligned} \sin^2 \phi - 1 + \cos \phi (\kappa + \kappa^{-1}) - \cos^2 \phi \\ &= \cos \phi [(\kappa + \kappa^{-1}) - 2 \cos \phi] \\ &= \cos \phi \sqrt{(\kappa - \cos \phi)^2 + \sin^2 \phi} \sqrt{(\kappa^{-1} - \cos \phi)^2 + \sin^2 \phi}. \end{aligned} \quad (\text{B14})$$

For  $\cos \phi = 0$ , Eq. (B14) is satisfied and it means that it is a solution of the SABS. In the case of  $\cos \phi \neq 0$ , Eq. (B13) becomes the same as Eq. (B12) when we choose plus sign in Eq. (B13). For  $\kappa - \cos \phi \geq 0$ , there always exists a solution of the SABS for arbitrary  $\phi$ .

(ii)  $\kappa - \cos \phi < 0$ .

Equation (B12) becomes

$$\begin{aligned} \pm(-\kappa + \kappa^{-1}) &= \sqrt{(\kappa - \cos \phi)^2 + \sin^2 \phi} \\ &\times \sqrt{(\kappa^{-1} - \cos \phi)^2 + \sin^2 \phi}. \end{aligned}$$

The negative sign of the left-hand side does not satisfy this equation. By taking the square of this equation, we obtain

$$\begin{aligned} (\kappa - \kappa^{-1})^2 &= 2 + (\kappa^2 + \kappa^{-2}) + 4 \cos^2 \phi - 4 \cos \phi (\kappa + \kappa^{-1}), \\ \Leftrightarrow \cos \phi &= \frac{1}{2} [\kappa + \kappa^{-1} \pm \sqrt{(\kappa - \kappa^{-1})^2}] \\ &= \kappa, \kappa^{-1}. \end{aligned}$$

The relation  $\cos \phi = \kappa$  contradicts  $\kappa - \cos \phi < 0$  and  $\cos \phi = \kappa^{-1}$  contradicts  $\kappa^{-1} \geq 1$ . Then, there is no solution of the SABS.

To summarize, if  $\sin \phi = \sin(-\phi_+ + \phi_-) \neq 0$  is satisfied, the energy dispersion of the SABS is given by

$$\begin{aligned} E(\mathbf{k}_{\parallel}) &= \frac{|\Delta_+| |\Delta_-| \sin \phi}{\sqrt{|\Delta_+|^2 + |\Delta_-|^2 - 2|\Delta_+| |\Delta_-| \cos \phi}} \\ &= \frac{|\Delta_+| |\Delta_-| \sin \phi}{|\Delta_+ - \Delta_-|}, \end{aligned}$$

$$\text{with } \left( \frac{|\Delta_+|}{|\Delta_-|} - \cos \phi \right) \left( \frac{|\Delta_-|}{|\Delta_+|} - \cos \phi \right) \geq 0.$$

For  $\sin \phi = 0$ ,

$$E(\mathbf{k}_{\parallel}) = 0,$$

$$\text{with } \frac{\Delta_+}{|\Delta_+|} = -\frac{\Delta_-}{|\Delta_-|}.$$

### APPENDIX C: CONDUCTANCE FOR GENERAL PAIR POTENTIAL

In this Appendix, we derive a conductance formula for any pair potential with single band superconductor where  $\hat{\varepsilon}(\mathbf{k})$  in Eq. (1) does not have an off-diagonal element. In Sec. C1, we introduce eigenvectors used for the wave function of superconducting side. In Sec. C2, we solve boundary conditions and derive conductance. In Sec. C3, we explain that the conductance is invariant under the spin rotation.

### 1. Derivation of eigenvectors

In this section, we derive the eigenvectors of the BdG Hamiltonian. In Eq. (7), we define  $\psi_{e,\sigma}^S$  and  $\psi_{h,\sigma}^S$  as

$$\begin{aligned}\psi_{e,\uparrow}^S &= \begin{pmatrix} u_{+,p} \\ v_{+,p} \end{pmatrix}, & \psi_{e,\downarrow}^S &= \begin{pmatrix} u_{+,m} \\ v_{+,m} \end{pmatrix}, \\ \psi_{h,\uparrow}^S &= \begin{pmatrix} v_{-,p} \\ u_{-,p} \end{pmatrix}, & \psi_{h,\downarrow}^S &= \begin{pmatrix} v_{-,m} \\ u_{-,m} \end{pmatrix}.\end{aligned}$$

$u_{\pm,p(m)}$  and  $v_{\pm,p(m)}$  satisfy

$$\begin{pmatrix} \tilde{\omega}_{+,p(m)}\sigma_0 & \Delta_+ \\ \Delta_+^\dagger & -\tilde{\omega}_{+,p(m)}\sigma_0 \end{pmatrix} \begin{pmatrix} u_{+,p(m)} \\ v_{+,p(m)} \end{pmatrix} = E \begin{pmatrix} u_{+,p(m)} \\ v_{+,p(m)} \end{pmatrix}, \quad (\text{C1})$$

$$\begin{pmatrix} -\tilde{\omega}_{-,p(m)}\sigma_0 & \Delta_- \\ \Delta_-^\dagger & \tilde{\omega}_{-,p(m)}\sigma_0 \end{pmatrix} \begin{pmatrix} v_{-,p(m)} \\ u_{-,p(m)} \end{pmatrix} = E \begin{pmatrix} v_{-,p(m)} \\ u_{-,p(m)} \end{pmatrix}, \quad (\text{C2})$$

where  $\sigma_0$  is the  $2 \times 2$  identity matrix and

$$\begin{aligned}\Delta_{\pm} &= [D_{\pm} + \mathbf{d}_{\pm} \cdot \boldsymbol{\sigma}]i\sigma_2 \\ \tilde{\omega}_{\pm,p} &= \sqrt{E^2 - (|\mathbf{d}_{\pm}|^2 + |D_{\pm}|^2 + |\mathbf{J}_{\pm}|)},\end{aligned} \quad (\text{C3})$$

$$\tilde{\omega}_{\pm,m} = \sqrt{E^2 - (|\mathbf{d}_{\pm}|^2 + |D_{\pm}|^2 - |\mathbf{J}_{\pm}|)}, \quad (\text{C4})$$

$$\mathbf{J}_{\pm} = \pm \mathbf{F}_{\pm} + \mathbf{q}_{\pm}$$

$$\mathbf{F}_{\pm} = D_{\pm} \mathbf{d}_{\pm}^* + D_{\pm}^* \mathbf{d}_{\pm},$$

$$\mathbf{q}_{\pm} = i \mathbf{d}_{\pm} \times \mathbf{d}_{\pm}^*,$$

with  $D_+ = D(\mathbf{k})$ ,  $D_- = D(\tilde{\mathbf{k}})$ ,  $\mathbf{d}_+ = \mathbf{d}(\mathbf{k})$ ,  $\mathbf{d}_- = \mathbf{d}(\tilde{\mathbf{k}})$  and  $\tilde{\mathbf{k}} = (k_x, k_y, -k_z)$ .  $\mathbf{F}_{\pm}$  and  $\mathbf{q}_{\pm}$  are real-valued functions and perpendicular to each other.  $D$  is a spin-singlet pair amplitude and  $\mathbf{d}$  is a triplet one.

From Eqs. (C1) and (C2), we obtain the following equations:

$$u_{+,p(m)}(E - \tilde{\omega}_{+,p(m)})(E + \tilde{\omega}_{+,p(m)}) = \Delta_+ \Delta_+^\dagger u_{+,p(m)}, \quad (\text{C5})$$

$$u_{-,p(m)}(E - \tilde{\omega}_{-,p(m)})(E + \tilde{\omega}_{-,p(m)}) = \Delta_-^\dagger \Delta_- u_{-,p(m)}. \quad (\text{C6})$$

To simplify the above equations, we define  $2 \times 2$  matrices as

$$\begin{aligned}\tilde{\omega}_{\pm,p(m)} &= \begin{pmatrix} \tilde{\omega}_{\pm,p} & 0 \\ 0 & \tilde{\omega}_{\pm,m} \end{pmatrix}, \\ u_{\pm} &= \begin{pmatrix} u_{\pm,p} & u_{\pm,m} \end{pmatrix}, \\ v_{\pm} &= \begin{pmatrix} v_{\pm,p} & v_{\pm,m} \end{pmatrix}.\end{aligned}$$

Equations (C5) and (C6) become

$$u_+(E\sigma_0 - \tilde{\omega}_{+,p(m)})(E\sigma_0 + \tilde{\omega}_{+,p(m)}) = \Delta_+ \Delta_+^\dagger u_+,$$

$$u_-(E\sigma_0 - \tilde{\omega}_{-,p(m)})(E\sigma_0 + \tilde{\omega}_{-,p(m)}) = \Delta_-^\dagger \Delta_- u_-.$$

$u_+$  and  $u_-$  are given by [86]

$$\begin{aligned}u_+ &= \tilde{a}_+(|\mathbf{J}_+|\sigma_0 + \mathbf{J}_+ \cdot \boldsymbol{\sigma})(\sigma_0 + \sigma_3) \\ &+ \tilde{b}_+(|\mathbf{J}_+|\sigma_0 - \mathbf{J}_+ \cdot \boldsymbol{\sigma})(\sigma_0 - \sigma_3),\end{aligned} \quad (\text{C7})$$

$$\begin{aligned}u_- &= \tilde{a}_-(|\mathbf{J}_-|\sigma_0 + \mathbf{J}_- \cdot \boldsymbol{\sigma}^*)(\sigma_0 + \sigma_3) \\ &+ \tilde{b}_-(|\mathbf{J}_-|\sigma_0 - \mathbf{J}_- \cdot \boldsymbol{\sigma}^*)(\sigma_0 - \sigma_3),\end{aligned} \quad (\text{C8})$$

with

$$\tilde{a}_{\pm}(\tilde{b}_{\pm}) = \sqrt{\frac{1}{16|\mathbf{J}_{\pm}|[|\mathbf{J}_{\pm}| + (\mathbf{J}_{\pm})_3]} \frac{E + \tilde{\omega}_{\pm,p(m)}}{E}}.$$

By using  $u_{\pm}$ ,  $v_{\pm}$  can be expressed as

$$v_+ = \Delta_+^\dagger u_+(E\sigma_0 + \tilde{\omega}_{+,p(m)})^{-1}, \quad (\text{C9})$$

$$v_- = \Delta_- u_-(E\sigma_0 + \tilde{\omega}_{-,p(m)})^{-1}. \quad (\text{C10})$$

### 2. Conductance

The tunneling conductance for a general pair potential is obtained by solving the following boundary conditions [Eqs. (13) and (14)]:

$$e_{\sigma} + \begin{pmatrix} b_{\sigma} \\ a_{\sigma} \end{pmatrix} = \begin{pmatrix} u_+ & v_- \\ v_+ & u_- \end{pmatrix} \begin{pmatrix} c \\ d \end{pmatrix}, \quad (\text{C11})$$

$$\begin{aligned}ik_z \begin{pmatrix} u_+ & v_- \\ v_+ & u_- \end{pmatrix} \begin{pmatrix} \sigma_0 & 0 \\ 0 & -\sigma_0 \end{pmatrix} \begin{pmatrix} c \\ d \end{pmatrix} - ik_z e_{\sigma} \\ + ik_z \begin{pmatrix} \sigma_0 & 0 \\ 0 & -\sigma_0 \end{pmatrix} \begin{pmatrix} b_{\sigma} \\ a_{\sigma} \end{pmatrix} = \frac{2mU_0}{\hbar^2} \left[ e_{\sigma} + \begin{pmatrix} b_{\sigma} \\ a_{\sigma} \end{pmatrix} \right],\end{aligned} \quad (\text{C12})$$

with

$$\begin{aligned}e_{\uparrow} &= (1, 0, 0, 0)^T, & e_{\downarrow} &= (0, 1, 0, 0)^T, & a_{\sigma} &= (a_{\sigma,\uparrow}, a_{\sigma,\downarrow})^T, \\ b_{\sigma} &= (b_{\sigma,\uparrow}, b_{\sigma,\downarrow})^T, & c &= (c_{\uparrow}, c_{\downarrow})^T, & d &= (d_{\uparrow}, d_{\downarrow})^T.\end{aligned}$$

We define

$$\hat{\Theta}_{\pm} = v_{\pm}(u_{\pm})^{-1}, \quad Z' = \frac{2mU_0}{k_z \hbar^2}, \quad G = \begin{pmatrix} u_+ & v_- \\ v_+ & u_- \end{pmatrix}.$$

From Eqs. (C9) and (C10),  $\hat{\Theta}_+$  and  $\hat{\Theta}_-$  satisfy

$$\hat{\Theta}_+ = \Delta_+^\dagger u_+(E\sigma_0 + \tilde{\omega}_{+,p(m)})^{-1} u_+^{-1},$$

$$\hat{\Theta}_- = \Delta_- u_-(E\sigma_0 + \tilde{\omega}_{-,p(m)})^{-1} u_-^{-1}.$$

We can check that following  $u_{\pm}^{-1}$  given by Eqs. (C13) and (C14) satisfy  $u_{\pm} u_{\pm}^{-1} = \sigma_0$ :

$$\begin{aligned}u_+^{-1} &= \check{a}_+(\sigma_0 + \sigma_3)(|\mathbf{J}_+|\sigma_0 + \mathbf{J}_+ \cdot \boldsymbol{\sigma}) \\ &+ \check{b}_+(\sigma_0 - \sigma_3)(|\mathbf{J}_+|\sigma_0 - \mathbf{J}_+ \cdot \boldsymbol{\sigma}),\end{aligned} \quad (\text{C13})$$

$$\begin{aligned}u_-^{-1} &= \check{a}_-(\sigma_0 + \sigma_3)(|\mathbf{J}_-|\sigma_0 + \mathbf{J}_- \cdot \boldsymbol{\sigma}^*) \\ &+ \check{b}_-(\sigma_0 - \sigma_3)(|\mathbf{J}_-|\sigma_0 - \mathbf{J}_- \cdot \boldsymbol{\sigma}^*),\end{aligned}$$

$$\begin{aligned}\check{a}_{\pm} &= \sqrt{\frac{1}{4|\mathbf{J}_{\pm}|[|\mathbf{J}_{\pm}| + (\mathbf{J}_{\pm})_3]} \frac{E}{E + \tilde{\omega}_{\pm,p}}}, \\ \check{b}_{\pm} &= \sqrt{\frac{1}{4|\mathbf{J}_{\pm}|[|\mathbf{J}_{\pm}| + (\mathbf{J}_{\pm})_3]} \frac{E}{E + \tilde{\omega}_{\pm,m}}},\end{aligned} \quad (\text{C14})$$

From Eqs. (C13) and (C14),  $\hat{\Theta}_+$  and  $\hat{\Theta}_-$  are obtained as

$$\hat{\Theta}_+ = \frac{\Delta_+^\dagger}{2} \left[ \left( \frac{1}{E + \tilde{\omega}_{+,p}} + \frac{1}{E + \tilde{\omega}_{+,m}} \right) + \left( \frac{1}{E + \tilde{\omega}_{+,p}} - \frac{1}{E + \tilde{\omega}_{+,m}} \right) \frac{\mathbf{J}_+}{|\mathbf{J}_+|} \cdot \boldsymbol{\sigma} \right],$$

$$\hat{\Theta}_- = \frac{\Delta_-}{2} \left[ \left( \frac{1}{E + \tilde{\omega}_{-,p}} + \frac{1}{E + \tilde{\omega}_{-,m}} \right) + \left( \frac{1}{E + \tilde{\omega}_{-,p}} - \frac{1}{E + \tilde{\omega}_{-,m}} \right) \frac{\mathbf{J}_-}{|\mathbf{J}_-|} \cdot \boldsymbol{\sigma}^* \right].$$

If  $\mathbf{F}_\pm + \mathbf{q}_\pm = 0$  is satisfied, from Eqs. (C3), (C4), (C9), and (C10), we obtain  $\tilde{\omega}_{\pm,p} = \tilde{\omega}_{\pm,m}$ , and

$$\hat{\Theta}_+ = \frac{\Delta_+^\dagger}{E + \tilde{\omega}_{+,p}}, \quad \hat{\Theta}_- = \frac{\Delta_-}{E + \tilde{\omega}_{-,p}}.$$

We obtain  $a_\sigma$  and  $b_\sigma$  from Eqs. (C11) and (C12):

$$\begin{pmatrix} b_\sigma \\ a_\sigma \end{pmatrix} = \left[ I_4 + G \begin{pmatrix} \sigma_0 & 0 \\ 0 & -\sigma_0 \end{pmatrix} G^{-1} \begin{pmatrix} (1 + iZ')\sigma_0 & 0 \\ 0 & (-1 + iZ')\sigma_0 \end{pmatrix} \right]^{-1} \left[ -I_4 + (1 - iZ')G \begin{pmatrix} \sigma_0 & 0 \\ 0 & -\sigma_0 \end{pmatrix} G^{-1} \right] e_\sigma,$$

where  $I_4$  is the  $4 \times 4$  identity matrix. From the general relation of  $2n \times 2n$  matrix,

$$\begin{pmatrix} A & B \\ C & D \end{pmatrix}^{-1} = \begin{pmatrix} (A - BD^{-1}C)^{-1} & (C - DB^{-1}A)^{-1} \\ (B - AC^{-1}D)^{-1} & (D - CA^{-1}B)^{-1} \end{pmatrix}, \quad (\text{C15})$$

where  $A, B, C,$  and  $D$  are  $n \times n$  regular matrices, we obtain the following relation:

$$G \begin{pmatrix} \sigma_0 & 0 \\ 0 & -\sigma_0 \end{pmatrix} G^{-1} = \begin{pmatrix} (\sigma_0 - \hat{\Theta}_- \hat{\Theta}_+)^{-1} (\sigma_0 + \hat{\Theta}_- \hat{\Theta}_+) & -2(\sigma_0 - \hat{\Theta}_- \hat{\Theta}_+)^{-1} \hat{\Theta}_- \\ 2(\sigma_0 - \hat{\Theta}_+ \hat{\Theta}_-)^{-1} \hat{\Theta}_+ & -(\sigma_0 - \hat{\Theta}_+ \hat{\Theta}_-)^{-1} (\sigma_0 + \hat{\Theta}_+ \hat{\Theta}_-) \end{pmatrix}.$$

We define  $2 \times 2$  matrices  $\alpha_{ij}$  as

$$\begin{pmatrix} \alpha_{11} & \alpha_{12} \\ \alpha_{21} & \alpha_{22} \end{pmatrix} = \left[ I_4 + G \begin{pmatrix} \sigma_0 & 0 \\ 0 & -\sigma_0 \end{pmatrix} G^{-1} \begin{pmatrix} (1 + iZ')\sigma_0 & 0 \\ 0 & (-1 + iZ')\sigma_0 \end{pmatrix} \right]^{-1}.$$

From Eq. (C15),  $\alpha_{ij}$  are obtained

$$\alpha_{11} = (2 - iZ') [Z^2 \hat{\Theta}_- \hat{\Theta}_+ - (4 + Z^2)\sigma_0]^{-1} (\hat{\Theta}_- \hat{\Theta}_+ - \sigma_0)^{-1} \left( \sigma_0 + \frac{-iZ'}{2 - iZ'} \hat{\Theta}_- \hat{\Theta}_+ \right) (\sigma_0 - \hat{\Theta}_- \hat{\Theta}_+),$$

$$\alpha_{22} = (2 + iZ') [Z^2 \hat{\Theta}_+ \hat{\Theta}_- - (4 + Z^2)\sigma_0]^{-1} (\hat{\Theta}_+ \hat{\Theta}_- - \sigma_0)^{-1} \left( \sigma_0 + \frac{iZ'}{2 + iZ'} \hat{\Theta}_+ \hat{\Theta}_- \right) (\sigma_0 - \hat{\Theta}_+ \hat{\Theta}_-),$$

$$\alpha_{12} = 2(-1 + iZ') [(4 + Z^2)\sigma_0 - Z^2 \hat{\Theta}_- \hat{\Theta}_+]^{-1} (\sigma_0 - \hat{\Theta}_- \hat{\Theta}_+)^{-1} \hat{\Theta}_- (\sigma_0 - \hat{\Theta}_+ \hat{\Theta}_-),$$

$$\alpha_{21} = -2(1 + iZ') [(4 + Z^2)\sigma_0 - Z^2 \hat{\Theta}_+ \hat{\Theta}_-]^{-1} (\sigma_0 - \hat{\Theta}_+ \hat{\Theta}_-)^{-1} \hat{\Theta}_+ (\sigma_0 - \hat{\Theta}_- \hat{\Theta}_+).$$

Finally,  $b_\sigma$  and  $a_\sigma$  are obtained

$$b_\sigma = \frac{-iZ'}{2 + iZ'} (\sigma_0 - \hat{\Theta}_- \hat{\Theta}_+) [\sigma_0 - (1 - \sigma_N) \hat{\Theta}_- \hat{\Theta}_+]^{-1} \tilde{e}_\sigma,$$

$$a_\sigma = \sigma_N \hat{\Theta}_+ [\sigma_0 - (1 - \sigma_N) \hat{\Theta}_- \hat{\Theta}_+]^{-1} \tilde{e}_\sigma,$$

where  $\tilde{e}_\sigma$  is defined by  $e_\sigma^\top = (\tilde{e}_\sigma^\top, 0, 0)$ . Then a general formula of the tunneling conductance is expressed compactly by using  $\hat{\Theta}_+$  and  $\hat{\Theta}_-$ :

$$\sigma_S = \frac{1}{2} \sum_\sigma [1 + a_\sigma^\dagger a_\sigma - b_\sigma^\dagger b_\sigma]$$

$$= \frac{\sigma_N}{2} \text{Tr} \{ [\sigma_0 - (1 - \sigma_N) \hat{\Theta}_+ \hat{\Theta}_+]^{-1} [\sigma_0 + \sigma_N \hat{\Theta}_+ \hat{\Theta}_+ + (\sigma_N - 1) \hat{\Theta}_+ \hat{\Theta}_- \hat{\Theta}_- \hat{\Theta}_+] [\sigma_0 - (1 - \sigma_N) \hat{\Theta}_- \hat{\Theta}_-]^{-1} \}. \quad (\text{C16})$$

### 3. Spin rotation

In this section, we explain that the conductance is invariant under the spin rotation. Under the spin rotation ( $\Psi \rightarrow U\Psi$ ),

$$U = \begin{pmatrix} R & 0 \\ 0 & R^* \end{pmatrix},$$

$$R = e^{-i\theta \cdot \boldsymbol{\sigma}/2},$$



pair potential  $\Delta_{\pm}$  and  $\mathbf{J}_{\pm}$  are transformed as

$$\begin{aligned}\Delta_{\pm} &\rightarrow R\Delta_{\pm}R^T \\ \mathbf{J}_{+} \cdot \boldsymbol{\sigma} &\rightarrow R\mathbf{J}_{+} \cdot \boldsymbol{\sigma}R^{\dagger}, \\ \mathbf{J}_{-} \cdot \boldsymbol{\sigma}^{*} &\rightarrow R^{*}\mathbf{J}_{-} \cdot \boldsymbol{\sigma}^{*}R^T.\end{aligned}$$

$\hat{\Theta}_{\pm}$  is transformed as

$$\begin{aligned}\hat{\Theta}_{+} &\rightarrow \frac{R^{*}\hat{\Delta}_{+}^{\dagger}R^{\dagger}}{2} \left[ \left( \frac{1}{E + \omega_{+,p}} + \frac{1}{E + \omega_{+,m}} \right) + \left( \frac{1}{E + \omega_{+,p}} - \frac{1}{E + \omega_{+,m}} \right) \frac{R\mathbf{J}_{+} \cdot \boldsymbol{\sigma}R^{\dagger}}{|\mathbf{J}_{+}|} \right] \\ &= R^{*}\hat{\Theta}_{+}R^{\dagger}, \\ \hat{\Theta}_{-} &\rightarrow \frac{R\hat{\Delta}_{-}R^T}{2} \left[ \left( \frac{1}{E + \omega_{-,p}} + \frac{1}{E + \omega_{-,m}} \right) + \left( \frac{1}{E + \omega_{-,p}} - \frac{1}{E + \omega_{-,m}} \right) \frac{R^{*}\mathbf{J}_{-} \cdot \boldsymbol{\sigma}^{*}R^T}{|\mathbf{J}_{-}|} \right] \\ &= R\hat{\Theta}_{-}R^T.\end{aligned}$$

Then the conductance is invariant under the spin rotation:

$$\begin{aligned}\sigma_S &\rightarrow \text{Tr}[\sigma_0 - (1 - \sigma_N)R\hat{\Theta}_{+}^{\dagger}R^TR^{*}\hat{\Theta}_{-}^{\dagger}R^{\dagger}]^{-1} [1 + \sigma_N R\hat{\Theta}_{+}^{\dagger}R^TR^{*}\hat{\Theta}_{+}R^{\dagger} + (\sigma_N - 1)R\hat{\Theta}_{+}^{\dagger}R^TR^{*}\hat{\Theta}_{-}^{\dagger}R^{\dagger}R\hat{\Theta}_{-}R^TR^{*}\hat{\Theta}_{+}R^{\dagger}] \\ &\quad \times [\sigma_0 - (1 - \sigma_N)R\hat{\Theta}_{-}R^TR^{*}\hat{\Theta}_{+}R^{\dagger}]^{-1} \\ &= \text{Tr}R[\sigma_0 - (1 - \sigma_N)\hat{\Theta}_{+}^{\dagger}\hat{\Theta}_{-}^{\dagger}]^{-1}R^{\dagger}R[1 + \sigma_N\hat{\Theta}_{+}^{\dagger}\hat{\Theta}_{+} + (\sigma_N - 1)\hat{\Theta}_{+}^{\dagger}\hat{\Theta}_{-}^{\dagger}\hat{\Theta}_{-}\hat{\Theta}_{+}]R^{\dagger}R[\sigma_0 - (1 - \sigma_N)\hat{\Theta}_{-}\hat{\Theta}_{+}]^{-1}R^{\dagger} \\ &= \sigma_S.\end{aligned}$$

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